

## LM5064 Negative Voltage System Power Management and Protection IC with PMBus

Check for Samples: [LM5064](#)

### FEATURES

- Input Voltage Range: -10V to -80V
- Programmable 26 mV or 50 mV Current Limit Threshold with Power Limiting (MOSFET Power Dissipation Limiting)
- Real Time Monitoring of  $V_{IN}$ ,  $V_{OUT}$ ,  $I_{IN}$ ,  $P_{IN}$ ,  $V_{AUX}$  with 12-Bit Resolution and 1 kHz Sampling Rate
- Configurable Circuit Breaker Protection for Hard Shorts
- Configurable Under-Voltage and Over-Voltage Protection
- Remote Temperature Sensing with Programmable Warning and Shutdown Thresholds
- Detection and Notification of Damaged MOSFET Condition
- Power Measurement Accuracy:  $\pm 4.5\%$  Over Temperature
- True Input Power Averages Dynamic Power Readings
- Averaging of  $V_{IN}$ ,  $I_{IN}$ ,  $P_{IN}$ , and  $V_{OUT}$  Over Programmable Interval Ranging from 0.001 to 4 Seconds
- Programmable **WARN** and **FAULT** Thresholds with **SMBA** Notification
- Black Box Capture of Telemetry Measurements and Device Status Triggered by **WARN** or **FAULT** Condition
- I<sup>2</sup>C/SMBus Interface and PMBus Compliant Command Structure
- Full Featured Application Development Software
- HTSSOP-28 Package

### APPLICATIONS

- Base Station Power Distribution Systems
- Intelligent Solid State Circuit Breaker
- -24V/-48V Industrial Systems

### DESCRIPTION

The LM5064 combines a high performance hot swap controller with a PMBus<sup>TM</sup> compliant SMBus/I<sup>2</sup>C interface to accurately measure, protect and control the electrical operating conditions of systems connected to a backplane power bus. The LM5064 continuously supplies real-time power, voltage, current, temperature and fault data to the system management host via the SMBus interface.

The LM5064 control block includes a unique hot swap architecture that provides current and power limiting to protect sensitive circuitry during insertion of boards into a live system backplane, or any other "hot" power source. A fast acting circuit breaker prevents damage in the event of a short circuit on the output. The input under-voltage and over-voltage levels and hysteresis are configurable, as well as the insertion delay time and fault detection time. A temperature monitoring block on the LM5064 interfaces with a low-cost external diode for monitoring the temperature of the external MOSFET or other thermally sensitive components. The PGD output provides a fast indicator when the input and/or output voltages are outside their programmed ranges.

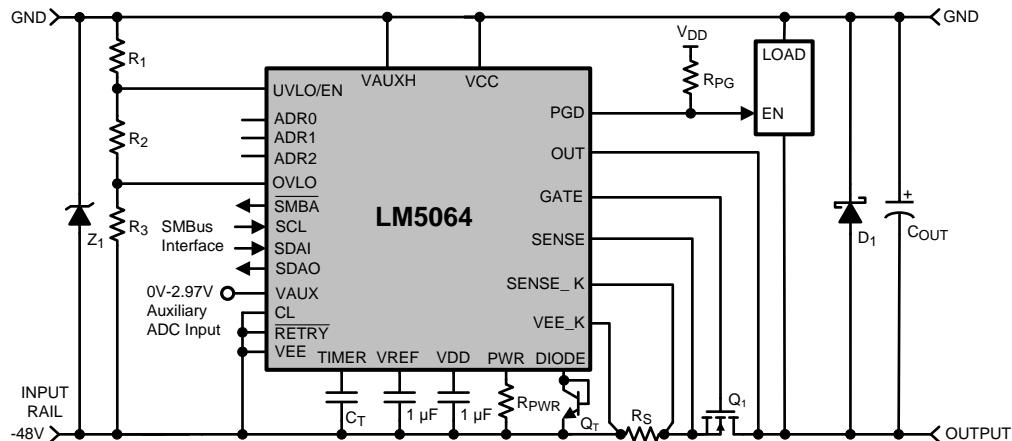
The LM5064 monitoring circuit computes both the real-time and average values of subsystem operating parameters ( $V_{IN}$ ,  $I_{IN}$ ,  $P_{IN}$ ,  $V_{OUT}$ ) as well as the peak power. Accurate power averaging is accomplished by averaging the product of the input voltage and current. A black box (Telemetry/Fault Snapshot) function captures and stores telemetry data and device status in the event of a warning or a fault.



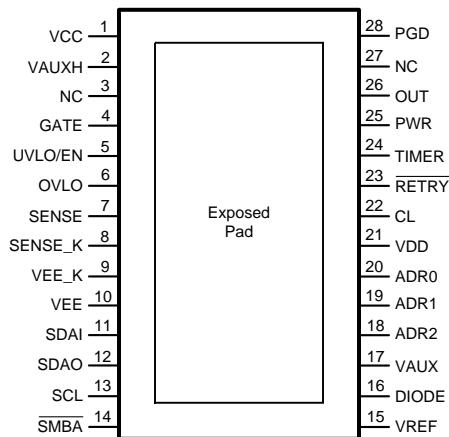
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## Typical Application Circuit



## Connection Diagram



**Top View  
28-Lead HTSSOP  
9.7 mm x 4.4 mm x 0.9 mm  
PWP0028A Package**

## PIN DESCRIPTIONS

| Pin# | Name    | Description  |
|------|---------|--|
| 1    | VCC     | Positive supply input. Connect the VCC pin to the positive voltage rail.   |
| 2    | VAUXH   | High voltage auxiliary input. VCC with respect to VEE is measured by connecting the VAUXH pin to the VCC rail.   |
| 3    | NC      | No connect. This pin is not internally connected and should not be connected to any signal or power rail.  |
| 4    | GATE    | MOSFET gate control signal for fault control of the output. The GATE pin is clamped to VEE through a 12.6V internal zener diode.   |
| 5    | UVLO/EN | Under-voltage lockout threshold input. Connecting the UVLO pin to a resistor divider from VCC to VEE will set the under-voltage lockout threshold. After the UVLO pin voltage falls below 2.48V, an internal 20 $\mu$ A current source is switched to provide a user settable hysteresis. The UVLO pin can be toggled directly to act as a precision enable. After the UVLO threshold voltage is exceeded, the output voltage will begin to transition to $V_{VEE}$ as the GATE pin supplies 52 $\mu$ A to turn on the MOSFET. |
| 6    | OVLO    | Over-voltage lockout threshold input. Connecting the OVLO pin to a resistor divider from VCC to VEE will set the over-voltage lockout threshold. After the OVLO pin voltage exceeds 2.47V, an internal 21 $\mu$ A current source is switched to provide a user settable hysteresis. If the OVLO threshold is exceeded, the MOSFET will be immediately disabled to protect the output.  |

**PIN DESCRIPTIONS (continued)**

| Pin# | Name    | Description   |
|------|---------|---|
| 7    | SENSE   | Current limit and power limit sense input. SENSE provides a direct connection to the MOSFET source and current sense resistor voltage to detect current limit and power limit events. This unfiltered signal will allow the LM5064 to quickly respond during over-current or over-power events.   |
| 8    | SENSE_K | Current telemetry Kelvin sense positive input. SENSE_K is the positive input to a precision differential current sense amplifier. Connecting SENSE_K to the positive terminal of the current sense resistor will provide an accurate current telemetry signal.  |
| 9    | VEE_K   | Current telemetry Kelvin sense negative input. The VEE_K pin is the negative input to a precision differential current sense amplifier. Connecting VEE_K to the negative terminal of the current sense resistor will provide an accurate current signal.  |
| 10   | VEE     | Negative supply input. Connect the VEE pin to the negative voltage supply rail. Use a small ceramic bypass capacitor (0.1 $\mu$ F) from the VEE pin to the VCC pin to suppress transient current spikes when the load switch is turned off. The operational voltage range for the VEE pin is -10V to -80V. The VEE pin absolute maximum voltage is -100V. |
| 11   | SDAI    | SMBus data input. The SDAI pin is designed to read PMBus commands using the SMBus communication protocol. SDAI can be connected to SDAO if desired.   |
| 12   | SDAO    | SMBus data output. The SDAO pin is designed to transmit PMBus commands using the SMBus communication protocol. SDAO can be connected to SDAI if desired.  |
| 13   | SCL     | SMBus clock input.  |
| 14   | SMBA    | SMBus alert. This pin is connected to an open drain MOSFET which pulls the pin to VEE if a fault is detected.   |
| 15   | VREF    | Internal ADC reference output. Connect a 1 $\mu$ F capacitor from the VREF pin to VEE to filter noise imposed on the internal reference output.   |
| 16   | DIODE   | Positive diode sense. The DIODE pin should be connected to the anode of a diode whose cathode is connected to VEE for temperature monitoring.   |
| 17   | VAUX    | Auxiliary pin allows voltage telemetry from an external source. Full scale input of 2.97V.  |
| 18   | ADR2    | Address pin 2. The address pins can be connected to VDD, VEE, or left open to set the PMBus address of the LM5064.  |
| 19   | ADR1    | Address pin 1. The address pins can be connected to VDD, VEE, or left open to set the PMBus address of the LM5064.  |
| 20   | ADR0    | Address pin 0. The address pins can be connected to VDD, VEE, or left open to set the PMBus address of the LM5064.  |
| 21   | VDD     | Internal 4.9V sub-regulator output. VDD must be connected and closely coupled to VEE through a 1 $\mu$ F ceramic bypass capacitor.  |
| 22   | CL      | Current limit threshold input. The LM5064 detects current limit events by sensing the voltage across a series resistor. The current limit threshold is set to 26 mV by connecting CL to VDD and 50 mV when CL is connected to VEE.  |
| 23   | RETRY   | Retry selection pin. Connecting RETRY to VDD sets the LM5064 to lockout after a fault condition is detected. Connecting RETRY to VEE sets the LM5064 to retry after a fault condition.  |
| 24   | TIMER   | Timing input. Set the insertion time delay and the fault timeout period by connecting a capacitor from the TIMER pin to VEE. The restart time is also set through the TIMER pin when in restart mode.   |
| 25   | PWR     | Power limit input. Connecting a resistor from PWR to VEE sets the maximum power dissipation allowed in the external MOSFET switch. Power is calculated using the current information through the current sense resistor and voltage sensed across the MOSFET.   |
| 26   | OUT     | Output voltage sense input. The OUT pin is used to sense the output voltage and calculate the power across the MOSFET switch.   |
| 27   | NC      | No connect. This pin is not internally connected and should not be connected to any signal or power rail.   |
| 28   | PGD     | Power good monitor output. Open-drain output pulls low during over-current, UVLO, and OVLO. An external pull-up resistor to VDD or external rail is required.   |
| EP   | EP      | Exposed pad. Connect to PCB VEE plane using multiple thermal vias.  |



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

**Absolute Maximum Ratings <sup>(1)</sup>**

|  |                |
|--|----------------|
| VCC, UVLO/EN, OUT, VAUXH, PGD to VEE   | -0.3V to 100V  |
| GATE to VEE  | -0.3V to 16V   |
| OVLO, TIMER, PWR to VEE  | -0.3V to 7V    |
| SENSE_K, SENSE, VEE_K to VEE   | -0.3V to +0.3V |
| SCL, SDAI, SDAO, SMB <sub>A</sub> , CL, ADR0, ADR1, ADR2, VDD, VAUX, DIODE, RETRY, VREF to VEE | -0.3V to 6V    |
| ESD Rating   |                |
| Human Body Model <sup>(2)</sup>  | 2 kV           |
| Storage Temperature  | -65°C to 150°C |
| Junction Temperature   | 150°C          |

(1) Absolute Maximum Ratings are limits beyond which damage to the device may occur. Operating Ratings are conditions under which operation of the device is intended to be functional. For specifications and test conditions, see the Electrical Characteristics.

(2) The human body model is a 100 pF capacitor discharged through a 1.5 kΩ resistor into each pin. 2 kV rating for all pins except GATE and PGD which are rated at 1.5 kV and 1 kV respectively.

**Operating Ratings**

|                              |                  |
|------------------------------|------------------|
| VCC supply voltage above VEE | 10V to +80V      |
| OUT voltage above VEE        | 0V to +80V       |
| PGD off voltage above VEE    | 0V to +80V       |
| Junction temperature         | -40°C to + 125°C |

## Electrical Characteristics

Limits in standard type are for  $T_J = 25^\circ\text{C}$  only; limits in boldface type apply over the junction temperature ( $T_J$ ) range of  $-40^\circ\text{C}$  to  $+125^\circ\text{C}$ . Minimum and Maximum limits are specified through test, design, or statistical correlation. Typical values represent the most likely parametric norm at  $T_J = 25^\circ\text{C}$ , and are provided for reference purposes only. Unless otherwise stated the following conditions apply:  $\text{VCC-VEE} = 48\text{V}$ . See <sup>(1)</sup> <sup>(2)</sup>.

| Symbol                       | Parameter                                  | Conditions   | Min         | Typ  | Max         | Units         |
|------------------------------|--|--|-------------|------|-------------|---------------|
| <b>Input (VCC)</b>           |  |  |             |      |             |               |
| $I_{\text{IN-EN}}$           | Input current, enabled                     | $\text{VCC - VEE} = 48\text{V}$ , $\text{UVLO/EN} = 5\text{V}$                           |             | 6    | <b>8</b>    | mA            |
| $\text{POR}_{\text{IT}}$     | Threshold voltage to start insertion timer | $\text{VCC - VEE}$ increasing  |             | 8    | <b>9.2</b>  | V             |
| $\text{POR}_{\text{EN}}$     | Threshold voltage to enable all functions  | $\text{VCC - VEE}$ increasing  |             | 8.7  | <b>9.9</b>  | V             |
| $\text{POR}_{\text{EN-HYS}}$ | $\text{POR}_{\text{EN}}$ hysteresis        | $\text{VCC - VEE}$ decreasing  |             | 170  |             | mV            |
| <b>Output (OUT)</b>          |  |  |             |      |             |               |
| $I_{\text{OUT-EN}}$          | OUT bias current, enabled                  | Enabled, $\text{OUT} = \text{VEE}$   |             | -100 |             | nA            |
| $I_{\text{OUT-DIS}}$         | OUT bias current, disabled <sup>(3)</sup>  | Disabled, $\text{OUT} = \text{VEE} + 48\text{V}$   |             | 135  |             | $\mu\text{A}$ |
| <b>OVLO/UVLO</b>             |  |  |             |      |             |               |
| $\text{UVLO}_{\text{TH}}$    | UVLO/EN threshold                          | UVLO/EN Falling  | <b>2.41</b> | 2.48 | <b>2.55</b> | V             |
| $\text{UVLO}_{\text{HYS}}$   | UVLO/EN hysteresis current                 | $\text{UVLO/EN} = \text{VEE} + 2\text{V}$  | <b>13</b>   | 20   | <b>26</b>   | $\mu\text{A}$ |
| $\text{UVLO}_{\text{DEL}}$   | UVLO delay                                 | Delay to GATE high   |             | 9    |             | $\mu\text{s}$ |
|                              |  | Delay to GATE low  |             | 12   |             | $\mu\text{s}$ |
| $\text{UVLO}_{\text{BIAS}}$  | UVLO/EN bias current                       | $\text{UVLO/EN} = \text{VEE} + 5\text{V}$  |             |      | <b>1</b>    | $\mu\text{A}$ |
| $\text{OVLO}_{\text{TH}}$    | OVLO threshold                             |  | <b>2.39</b> | 2.47 | <b>2.53</b> | V             |
| $\text{OVLO}_{\text{HYS}}$   | OVLO hysteresis current                    | $\text{OVLO} = \text{VEE} + 2.8\text{V}$   | <b>-26</b>  | -21  | <b>-13</b>  | $\mu\text{A}$ |
| $\text{OVLO}_{\text{DEL}}$   | OVLO delay                                 | Delay to GATE high   |             | 10   |             | $\mu\text{s}$ |
|                              |  | Delay to GATE low  |             | 12   |             | $\mu\text{s}$ |
| $\text{OVLO}_{\text{BIAS}}$  | OVLO bias current                          | $\text{OVLO} = 2.3\text{V}$  |             |      | <b>1</b>    | $\mu\text{A}$ |
| <b>Power Limit (PWR)</b>     |  |  |             |      |             |               |
| $\text{PWR}_{\text{LIM-1}}$  | Power limit sense voltage (OUT-SENSE)      | $\text{OUT} - \text{SENSE} = 48\text{V}$ , $\text{RPWR} = 145\text{ k}\Omega$            | <b>19.5</b> | 24.5 | <b>29.5</b> | mV            |
| $\text{PWR}_{\text{LIM-2}}$  |  | $\text{OUT} - \text{SENSE} = 24\text{V}$ , $\text{RPWR} = 75\text{ k}\Omega$             |             | 24.7 |             | mV            |
| $I_{\text{PWR}}$             | PWR pin current                            | $V_{\text{PWR}} = 2.5\text{V}$   |             | -18  |             | $\mu\text{A}$ |
| $R_{\text{SAT(PWR)}}$        | PWR pin impedance when disabled            | $\text{UVLO/EN} = 2.0\text{V}$   |             | 140  |             | $\Omega$      |
| <b>Gate Control (GATE)</b>   |  |  |             |      |             |               |
| $I_{\text{GATE}}$            | Source current                             | Normal Operation   | <b>-72</b>  | -52  | <b>-32</b>  | $\mu\text{A}$ |
|                              | Sink current                               | $\text{UVLO/EN} < \text{VEE} + 2\text{V}$  | <b>3.4</b>  | 4.1  | <b>5.3</b>  | mA            |
|                              |  | $\text{SENSE} - \text{VEE} = 150\text{ mV}$ , $V_{\text{GATE}} = \text{VEE} + 5\text{V}$ | <b>50</b>   | 111  | <b>180</b>  | mA            |
| $V_{\text{GATE}}$            | Gate output voltage in normal operation    | GATE-VEE Voltage   |             | 12.6 |             | V             |
| <b>Current Limit</b>         |  |  |             |      |             |               |
| $V_{\text{CL}}$              | Current limit threshold voltage            | $\text{CL} = \text{VDD}$ <sup>(4)</sup>  | <b>23</b>   | 26   | <b>30</b>   | mV            |
| $V_{\text{CL}}$              | Current limit threshold voltage            | $\text{CL} = \text{VEE}$ or FLOAT <sup>(4)</sup>   | <b>47</b>   | 50   | <b>53</b>   | mV            |
| $t_{\text{CL}}$              | Response time                              | SENSE-VEE stepped from 0 mV to 80 mV   |             | 54   |             | $\mu\text{s}$ |
| $I_{\text{SENSE}}$           | SENSE input current                        | Enabled, $\text{OUT} = \text{VEE}$   |             | -5   |             | $\mu\text{A}$ |
|                              |  | Disabled, $\text{OUT} = \text{VCC}$  |             | -55  |             | $\mu\text{A}$ |
| $I_{\text{SENSE\_K}}$        | SENSE_K input current                      |  |             | -10  |             | $\mu\text{A}$ |

- (1) Absolute Maximum Ratings are limits beyond which damage to the device may occur. Operating Ratings are conditions under which operation of the device is intended to be functional. For specifications and test conditions, see the Electrical Characteristics.
- (2) Current out of a pin is indicated as a negative value.
- (3) OUT bias current (disabled) due to leakage current through an internal 1 M $\Omega$  resistance from SENSE to OUT.
- (4) CL bit High or Low is set by either the CL pin on startup (if CL = VDD, then High, if CL = VEE or FLOAT, then Low) or by the current limit setting bit in the device setup register.

## Electrical Characteristics (continued)

Limits in standard type are for  $T_J = 25^\circ\text{C}$  only; limits in boldface type apply over the junction temperature ( $T_J$ ) range of  $-40^\circ\text{C}$  to  $+125^\circ\text{C}$ . Minimum and Maximum limits are specified through test, design, or statistical correlation. Typical values represent the most likely parametric norm at  $T_J = 25^\circ\text{C}$ , and are provided for reference purposes only. Unless otherwise stated the following conditions apply:  $\text{VCC-VEE} = 48\text{V}$ . See <sup>(1)</sup> <sup>(2)</sup>.

| Symbol                                   | Parameter  | Conditions  | Min         | Typ     | Max         | Units         |
|--|--|---|-------------|---------|-------------|---------------|
| $I_{VEE\_K}$                             | VEE_K input current  |   |             | -10     |             | $\mu\text{A}$ |
| <b>Circuit Breaker</b>                   |  |   |             |         |             |               |
| $R_{TCB}$                                | Circuit breaker to current limit ratio: $(V_{SENSE}-V_{VEE})/V_{CL}$ | CB/CL ratio bit = 0, $ILim = 50\text{ mV}$                | <b>1.45</b> | 1.9     | <b>2.22</b> |               |
|  |  | CB/CL ratio bit = 1, $ILim = 50\text{ mV}$                | <b>2.8</b>  | 3.7     | <b>4.9</b>  |               |
|  |  | CB/CL ratio bit = 0, $ILim = 26\text{ mV}$                |             | 1.8     |             |               |
|  |  | CB/CL ratio bit = 1, $ILim = 26\text{ mV}$                |             | 3.6     |             |               |
| $V_{CB}$                                 | Circuit breaker threshold voltage: $(V_{SENSE}-V_{VEE})$             | CB/CL ratio bit = 0, $ILim = 50\text{ mV}$                | <b>72</b>   | 93      | <b>116</b>  | $\text{mV}$   |
|  |  | CB/CL ratio bit = 1, $ILim = 50\text{ mV}$                | <b>144</b>  | 187     | <b>230</b>  | $\text{mV}$   |
|  |  | CB/CL ratio bit = 0, $ILim = 26\text{ mV}$                | <b>37</b>   | 49      | <b>59</b>   | $\text{mV}$   |
|  |  | CB/CL ratio bit = 1, $ILim = 26\text{ mV}$                | <b>72</b>   | 93      | <b>116</b>  | $\text{mV}$   |
| $t_{CB}$                                 | Circuit breaker response time  | SENSE-VEE stepped from 0 mV to 150 mV, time to GATE = VEE |             | 800     |             | ns            |
| <b>Timer (TIMER)</b>                     |  |   |             |         |             |               |
| $V_{TMRH}$                               | Upper threshold  |   | <b>3.74</b> | 3.9     | <b>4.07</b> | $\text{V}$    |
| $V_{TMRL}$                               | Lower threshold  | Restart cycles  | <b>1.09</b> | 1.2     | <b>1.39</b> | $\text{V}$    |
|  |  | End of 8th cycle  |             | 0.3     |             | $\text{V}$    |
|  |  | Re-enable threshold                                       |             | 0.3     |             | $\text{V}$    |
| $I_{TIMER}$                              | Insertion time current   |   | <b>-5.9</b> | -4.8    | <b>-3.3</b> | $\mu\text{A}$ |
|  | Sink current, end of insertion time                                  | TIMER pin = VEE+2V  | <b>1</b>    | 1.5     | <b>2</b>    | $\text{mA}$   |
|  | Fault detection current  | $SENSE-VEE=V_{CL}$  | <b>-95</b>  | -74     | <b>-50</b>  | $\mu\text{A}$ |
|  | Fault sink current   |   | <b>1.7</b>  | 2.4     | <b>3.2</b>  | $\mu\text{A}$ |
| $DC_{FAULT}$                             | Fault restart duty cycle   |   |             | 0.5     |             | %             |
| $t_{FAULT}$                              | Fault to GATE = VEE delay  | TIMER pin reaches the upper threshold                     |             | 15      |             | $\mu\text{s}$ |
| <b>Power Good (PGD)</b>                  |  |   |             |         |             |               |
| $PGD_{TH}$                               | Threshold measured at OUT - SENSE                                    | OUT – SENSE Decreasing                                    | <b>1.18</b> | 1.24    | <b>1.31</b> | $\text{V}$    |
|  |  | OUT – SENSE Increasing                                    | <b>2.44</b> | 2.5     | <b>2.56</b> | $\text{V}$    |
| $PGD_{VOL}$                              | Output low voltage   | $I_{SINK} = 2\text{ mA}$                                  |             | 50      | <b>150</b>  | $\text{mV}$   |
| $PGD_{IOH}$                              | Off leakage current  | $V_{PGD} = 80\text{V}$                                    |             |         | <b>5</b>    | $\mu\text{A}$ |
| <b>ADC and MUX</b>                       |  |   |             |         |             |               |
|  | Resolution   |   |             | 12      |             | Bits          |
| INL                                      | Integral non-linearity   | ADC only  |             | $\pm 4$ |             | LSB           |
| $t_{ACQUIRE}$                            | Acquisition + conversion time  | Any Channel   |             | 100     |             | $\mu\text{s}$ |
| $t_{RR}$                                 | Acquisition round robin time   | Cycle all channels  |             | 1       |             | ms            |
| <b>Internal Reference</b>                |  |   |             |         |             |               |
| $V_{REF}$                                | Reference voltage  |   | <b>2.93</b> | 2.97    | <b>3.02</b> | $\text{V}$    |
| <b>Telemetry Accuracy</b> <sup>(5)</sup> |  |   |             |         |             |               |
| $IIN_{FSR}$                              | Current input full scale range                                       | CL= VEE <sup>(6)</sup>                                    |             | 74.9    |             | $\text{mV}$   |
|  |  | CL = VDD <sup>(6)</sup>                                   |             | 38.1    |             | $\text{mV}$   |
| $IIN_{LSB}$                              | Current input LSB  | CL= VEE <sup>(6)</sup>                                    |             | 18.3    |             | $\mu\text{V}$ |
|  |  | CL = VDD <sup>(6)</sup>                                   |             | 9.3     |             | $\mu\text{V}$ |
| $VAUX_{FSR}$                             | VAUX input full scale range  |   |             | 2.96    |             | $\text{V}$    |

(5) Full scale range depends on both the VREF value and the gain/attenuation of the current/voltage channel.

(6) CL bit High or Low is set by either the CL pin on startup (if CL = VDD, then High, if CL = VEE or FLOAT, then Low) or by the current limit setting bit in the device setup register.

## Electrical Characteristics (continued)

Limits in standard type are for  $T_J = 25^\circ\text{C}$  only; limits in boldface type apply over the junction temperature ( $T_J$ ) range of  $-40^\circ\text{C}$  to  $+125^\circ\text{C}$ . Minimum and Maximum limits are specified through test, design, or statistical correlation. Typical values represent the most likely parametric norm at  $T_J = 25^\circ\text{C}$ , and are provided for reference purposes only. Unless otherwise stated the following conditions apply:  $\text{VCC-VEE} = 48\text{V}$ . See <sup>(1)</sup> <sup>(2)</sup>.

| Symbol                      | Parameter                    | Conditions   | Min         | Typ  | Max        | Units         |
|-----------------------------|------------------------------|--|-------------|------|------------|---------------|
| $\text{VAUX}_{\text{LSB}}$  | VAUX input LSB               |  |             | 724  |            | $\mu\text{V}$ |
| $\text{VAUXH}_{\text{FSR}}$ | VAUXH input full scale range |  |             | 88.9 |            | V             |
| $\text{VAUXH}_{\text{LSB}}$ | VAUXH input LSB              |  |             | 21.7 |            | $\text{mV}$   |
| $\text{OUT}_{\text{LSB}}$   | OUT pin LSB                  |  |             | 21.7 |            | $\text{mV}$   |
| $\text{IIN}_{\text{ACC}}$   | Input current accuracy       | $\text{SENSE\_K-VEE\_K} = 50\text{ mV}$ , $\text{CL} = \text{VEE}$ (Note 6)                        | <b>-3.0</b> |      | <b>3.0</b> | %             |
| $\text{V}_{\text{ACC}}$     | VAUX, VAUXH, OUT             | $\text{VAUXH-VEE}=48\text{V}$ , $\text{OUT - VEE} = 48\text{V}$ , $\text{VAUX} = 2.8\text{V}$      | <b>-2.7</b> |      | <b>2.7</b> | %             |
| $\text{PIN}_{\text{ACC}}$   | Input power accuracy         | $\text{VCC-VEE} = 48\text{V}$ , $\text{SENSE\_K-VEE\_K} = 50\text{ mV}$ , $\text{CL} = \text{VDD}$ | <b>-4.5</b> |      | <b>4.5</b> | %             |

### Diode Temperature Sensor

|                           |  |   |  |      |            |                  |
|---------------------------|--|---|--|------|------------|------------------|
| $\text{T}_{\text{ACC}}$   | Temperature accuracy using local diode | $\text{T}_A = 25^\circ\text{C}$ to $85^\circ\text{C}$ |  | 2    |            | $^\circ\text{C}$ |
|                           | Remote diode resolution                |   |  | 9    |            | bits             |
| $\text{I}_{\text{DIODE}}$ | External diode current source          | High Level  |  | 250  | <b>325</b> | $\mu\text{A}$    |
|                           |  | Low Level   |  | 9.4  |            | $\mu\text{A}$    |
|                           | Diode current ratio                    |   |  | 25.9 |            |                  |

### VAUX

|                        |               |                           |  |  |          |               |
|------------------------|---------------|---------------------------|--|--|----------|---------------|
| $\text{I}_{\text{IN}}$ | Input current | $\text{VAUX} = 3\text{V}$ |  |  | <b>1</b> | $\mu\text{A}$ |
|------------------------|---------------|---------------------------|--|--|----------|---------------|

### VDD Regulation

|                            |                             |                              |            |     |             |    |
|----------------------------|-----------------------------|------------------------------|------------|-----|-------------|----|
| $\text{VDD}_{\text{OUT}}$  | VDD regulated output        | $\text{IDD} = 0\text{ mA}$   | <b>4.6</b> | 4.9 | <b>5.15</b> | V  |
|                            |                             | $\text{IDD} = -10\text{ mA}$ |            | 4.8 |             | V  |
| $\text{VDD}_{\text{ILIM}}$ | VDD current limit           | $\text{VDD} = 0\text{V}$     | <b>-25</b> | -30 | <b>-42</b>  | mA |
| $\text{VDD}_{\text{POR}}$  | VDD voltage reset threshold | $\text{VDD}$ Rising          |            | 4.1 |             | V  |

### PMBus Pin Thresholds (SCL, SDAI/O, SMBA) <sup>(7)</sup>

|                          |                                |  |            |  |            |               |
|--------------------------|--------------------------------|--|------------|--|------------|---------------|
| $\text{V}_{\text{IL}}$   | Data, clock input low voltage  | With respect to VEE                            |            |  | <b>0.9</b> | V             |
| $\text{V}_{\text{IH}}$   | Data, clock input high voltage | With respect to VEE                            | <b>2.1</b> |  | <b>5.5</b> | V             |
| $\text{V}_{\text{OL}}$   | Data output low voltage        | $\text{I}_{\text{SINK}} = 3\text{ mA}$         | <b>0</b>   |  | <b>0.4</b> | $\mu\text{A}$ |
| $\text{I}_{\text{LEAK}}$ | Input leakage current          | $\text{SDAI, SMBA, SCL} = 5\text{V}$ above VEE |            |  | <b>1</b>   | $\mu\text{A}$ |

### Pin Strappable Thresholds (CL, RETRY)

|                          |                       |                                |          |   |  |               |
|--------------------------|-----------------------|--------------------------------|----------|---|--|---------------|
| $\text{V}_{\text{IH}}$   | Input high voltage    |                                | <b>3</b> |   |  | V             |
| $\text{I}_{\text{LEAK}}$ | Input leakage current | $\text{CL, RETRY} = 5\text{V}$ |          | 5 |  | $\mu\text{A}$ |

### Thermal <sup>(8)</sup>

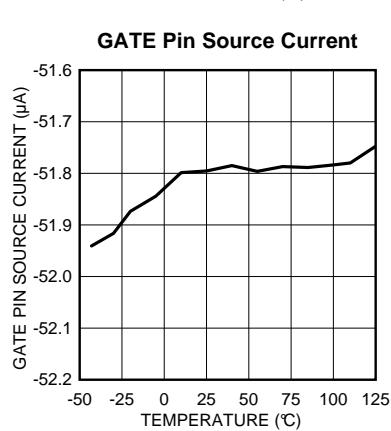
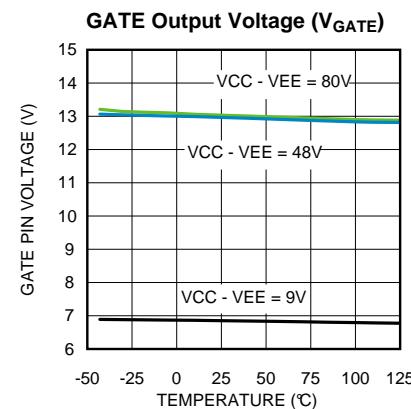
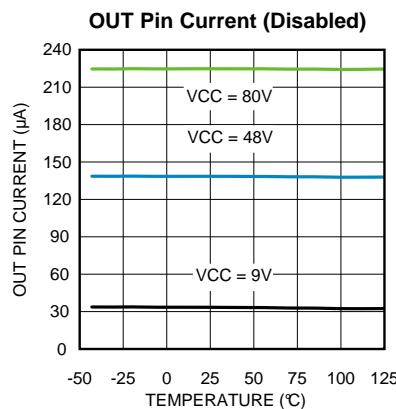
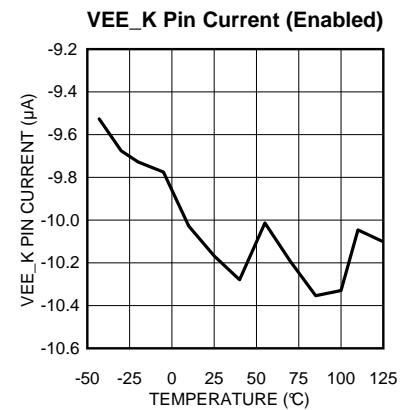
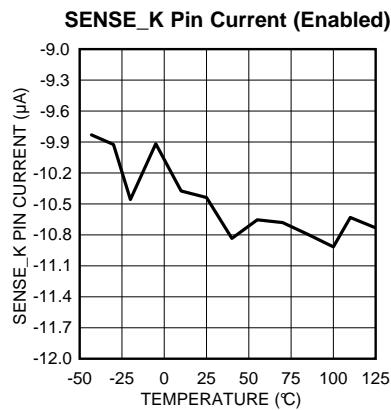
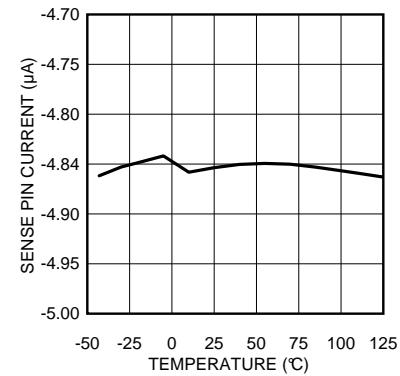
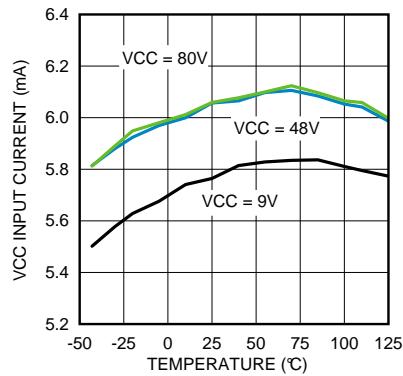
|                      |                     |  |  |    |  |                    |
|----------------------|---------------------|--|--|----|--|--------------------|
| $\theta_{\text{JA}}$ | Junction to ambient |  |  | 30 |  | $^\circ\text{C/W}$ |
| $\theta_{\text{JC}}$ | Junction to case    |  |  | 4  |  | $^\circ\text{C/W}$ |

(7) PMBus communication clock rate at final test is 400 kHz.

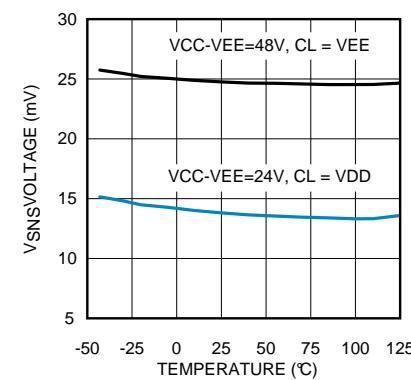
(8) Junction to ambient thermal resistance is highly application and board layout dependent. Specified thermal resistance values for the package specified is based on a 4-layer, 4"x3", 2/1/2 oz. Cu board as per JEDEC standards is used. For detailed information on soldering plastic HTSSOP packages refer to the Packaging Data Book.

## Typical Performance Characteristics

Unless otherwise specified the following conditions apply:  $T_J = 25^\circ\text{C}$ ,  $\text{VCC}-\text{VEE} = 48\text{V}$ .  
**VCC Pin Current**



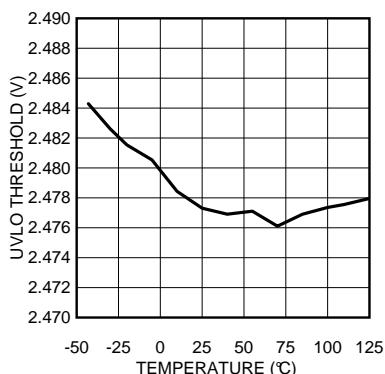
$V_{\text{SNS}}$  (SENSE\_K-VEE\_K) at Power Limit Threshold  $R_{\text{PWR}} = 75\text{ k}\Omega$



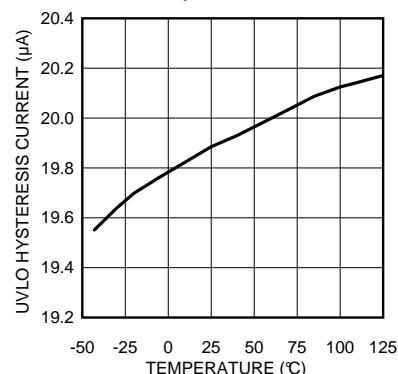
### Typical Performance Characteristics (continued)

Unless otherwise specified the following conditions apply:  $T_J = 25^\circ\text{C}$ ,  $\text{VCC-VEE} = 48\text{V}$ .

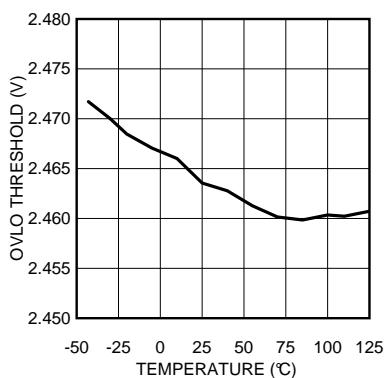
**UVLO Threshold**



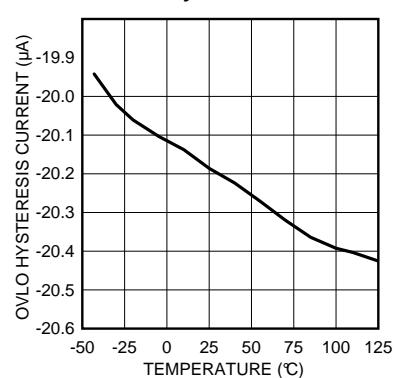
**UVLO Hysteresis Current**



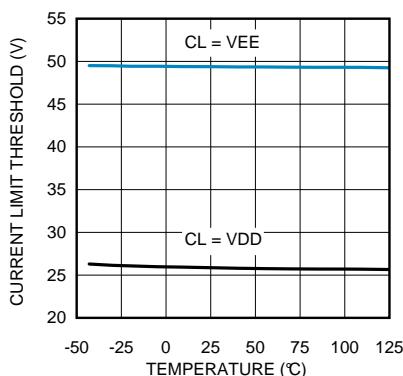
**OVLO Threshold**



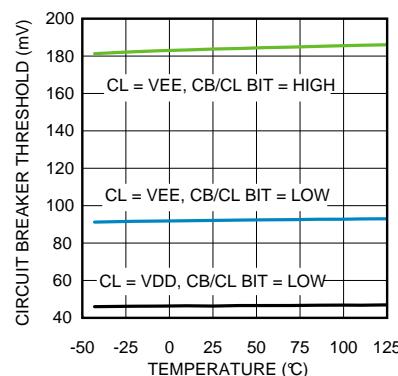
**OVLO Hysteresis Current**



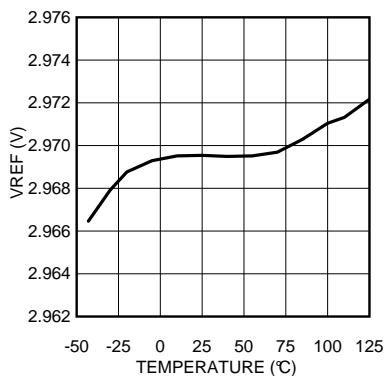
**Current Limit Threshold**



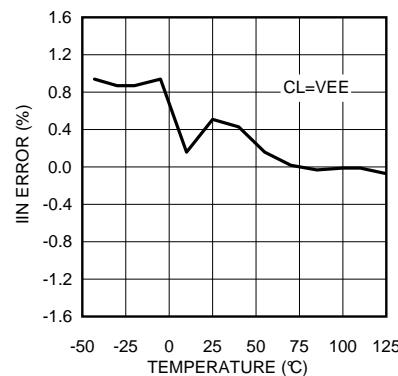
**Circuit Breaker Threshold**



**Reference Voltage**



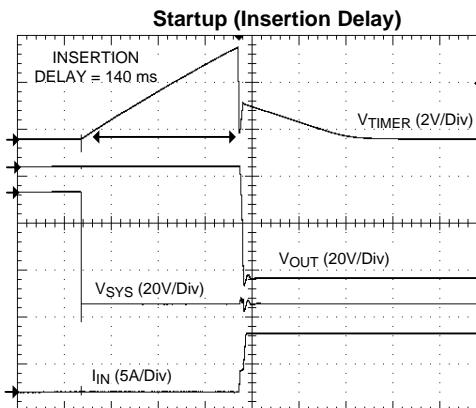
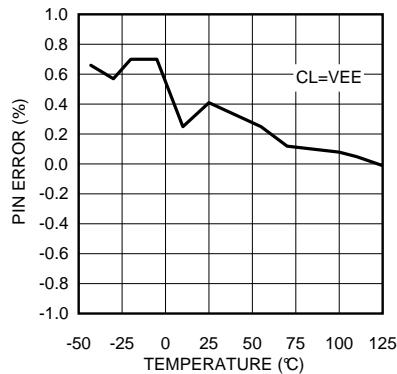
**IIN Measurement Accuracy (SENSE\_K-VEE\_K = 50 mV)**



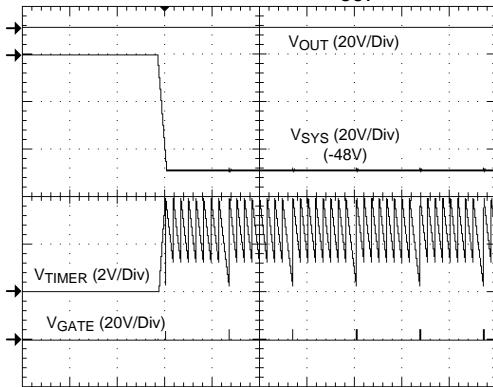
### Typical Performance Characteristics (continued)

Unless otherwise specified the following conditions apply:  $T_J = 25^\circ\text{C}$ ,  $V_{CC}-V_{EE} = 48\text{V}$ .

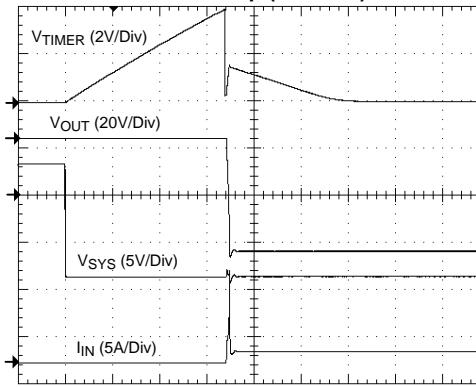
#### PIN Measurement Accuracy (SENSE\_K- $V_{EE}$ \_K = 50 mV)



#### Short Circuit $V_{OUT}$

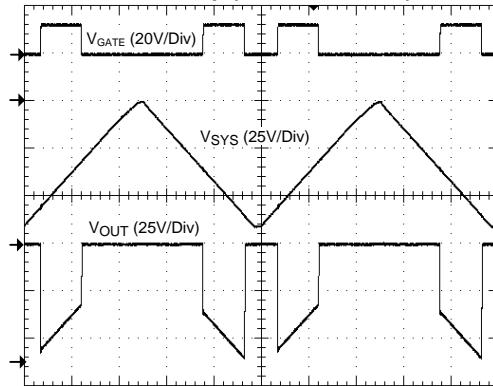


#### Startup (1A Load)



1s/div

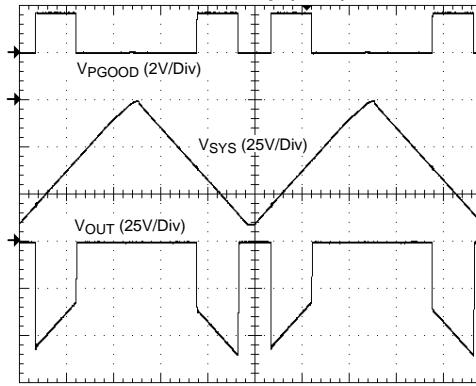
#### Startup (UVLO/EN, OVLO)



400 ms/div

40 ms/div

#### Startup (PGD)

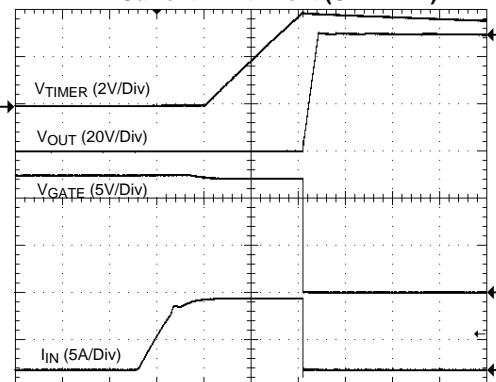


400 ms/div

### Typical Performance Characteristics (continued)

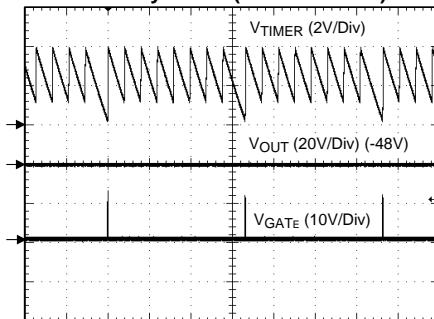
Unless otherwise specified the following conditions apply:  $T_J = 25^\circ\text{C}$ ,  $V_{CC-VEE} = 48\text{V}$ .

#### Current Limit Event ( $CL = V_{DD}$ )

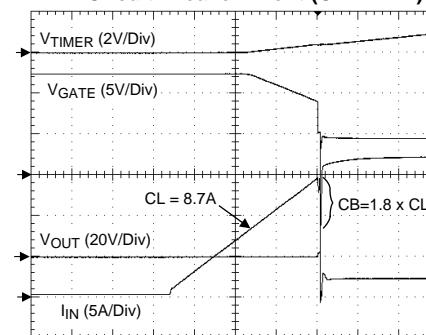


4 ms/div

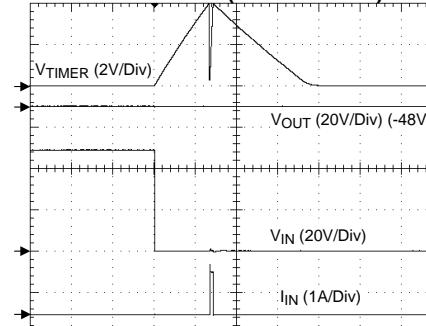
#### Retry Event ( $\text{RETRY} = V_{EE}$ )



#### Circuit Breaker Event ( $CL = V_{DD}$ )



#### Latch Off ( $\text{RETRY} = V_{DD}$ )



## BLOCK DIAGRAM

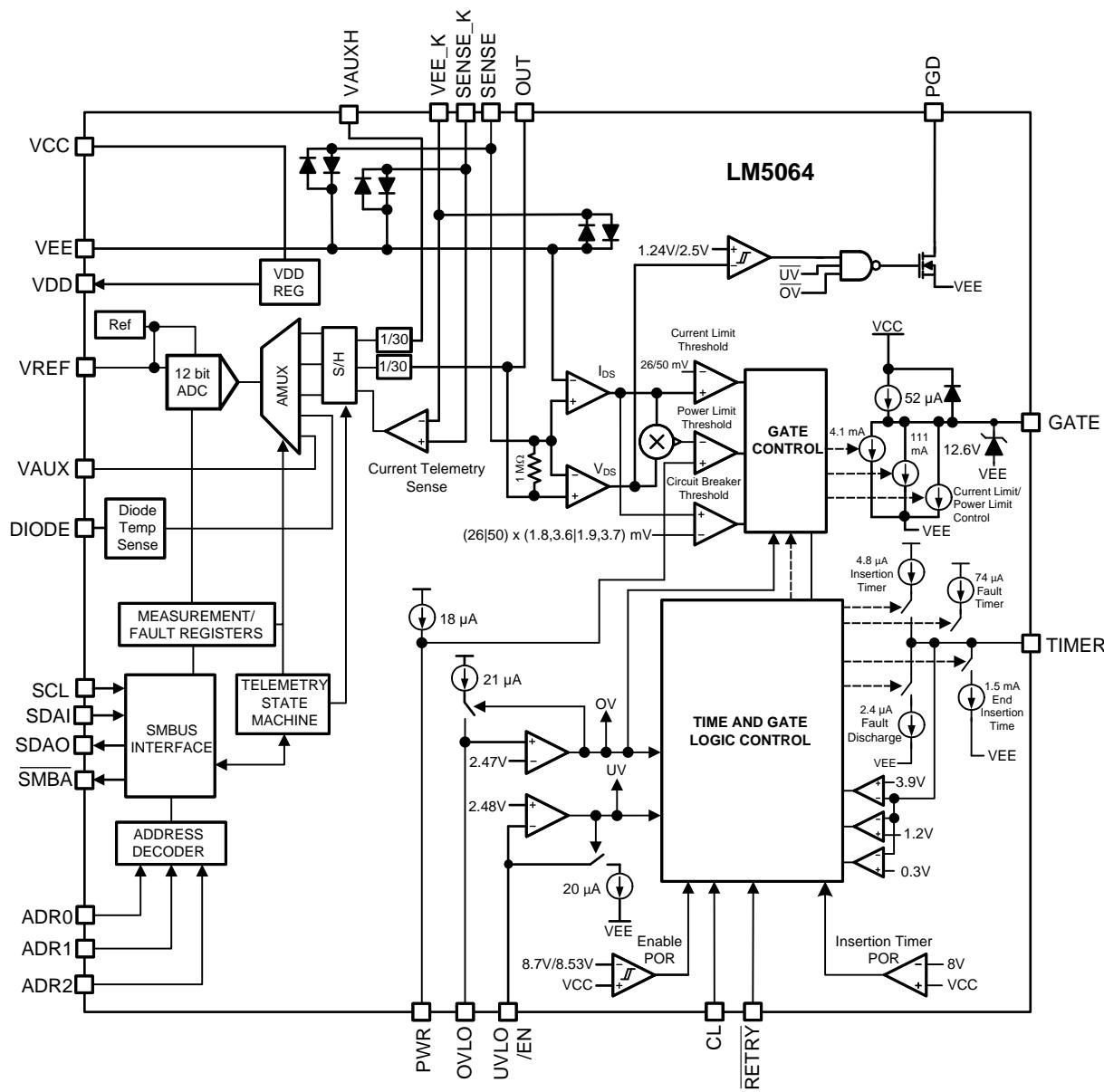


Figure 1. Block Diagram

## FUNCTIONAL DESCRIPTION

The LM5064 is designed to control the in-rush current to the load upon insertion of a circuit card into a live backplane or other “hot” power source, thereby limiting the voltage sag on the backplane’s supply and the dv/dt of the voltage applied to the load. The effect from the insertion event on other circuits in the system is minimized, preventing possible unintended resets. A controlled shutdown when the circuit card is removed can also be implemented using the LM5064.

In addition to a programmable current limit, the LM5064 monitors and limits the maximum power dissipation in the series pass device ( $Q_1$ ) to maintain operation within the device’s Safe Operating Area (SOA). Either current limiting or power limiting for an extended period of time (user defined) results in the shutdown of the series pass device. In this event, the LM5064 can latch off or repetitively retry based on the hardware setting of the **RETRY** pin. Once started, the number of retries can be set to 0, 1, 2, 4, 8, 16, or infinite. The circuit breaker function quickly switches off the series pass device upon detection of a severe over-current condition. Programmable under-voltage lockout (UVLO) and over-voltage lockout (OVLO) circuits shut down the LM5064 when the system input voltage ( $V_{SYS}$ ) is outside the desired operating range.

The telemetry capability of the LM5064 provides intelligent monitoring of the input voltage, output voltage, input current, input power, temperature, and an auxiliary input. The LM5064 also provides a peak capture of the input power and programmable hardware averaging of the input voltage, current, power, and output voltage. Warning thresholds which trigger the **SMBA** pin may be programmed for input and output voltage, current, power and temperature via the PMBus interface. Additionally, the LM5064 is capable of detecting damage to the external MOSFET,  $Q_1$ .

### Operating Voltage

The LM5064 operating voltage is the voltage supplied between VCC and VEE (VCC-VEE) which has an operating range of 10V to 80V with a 100V transient capability. All signals to the IC are referenced to the VEE voltage which acts as the effective return path for the IC.

### Power Up Sequence

Referring to [Figure 2](#), as the system voltage ( $V_{SYS}$ ) initially increases, the external N-channel MOSFET ( $Q_1$ ) is held off by an internal 111 mA pull-down current at the GATE pin. The strong pull-down current at the GATE pin prevents an inadvertent turn on as the MOSFET’s gate-to-drain (Miller) capacitance is charged. Additionally, the TIMER pin is initially held at VEE. When the operating voltage of the LM5064 (VCC - VEE) reaches the **POR<sub>IT</sub>** threshold, the insertion time begins. During the insertion time, the capacitor at the TIMER pin ( $C_T$ ) is charged by a 4.8  $\mu$ A current source, and  $Q_1$  is held off by a 4.1 mA pull-down current at the GATE pin regardless of the input voltage. The insertion time delay allows ringing and transients on  $V_{SYS}$  to settle before  $Q_1$  is enabled. The insertion time ends when the TIMER pin voltage reaches 3.9V.  $C_T$  is then quickly discharged by an internal 1.5 mA pull-down current. The GATE pin then switches on  $Q_1$  when the operating voltage exceeds the UVLO threshold. If the operating voltage is above the UVLO threshold at the end of the insertion time, ( $t_1$  in [Figure 2](#)) the GATE pin sources 52  $\mu$ A to charge the gate capacitance of  $Q_1$ . The maximum voltage on GATE is limited by an internal 12.6V zener diode to VEE.

As the voltage at the OUT pin transitions to  $V_{SYS}$ , the LM5064 monitors the drain current and power dissipation of MOSFET  $Q_1$ . In-rush current limiting and/or power limiting circuits actively control the current delivered to the load. During the in-rush limiting interval ( $t_2$  in [Figure 2](#)), an internal 74  $\mu$ A fault timer current source charges  $C_T$ . If  $Q_1$ ’s power dissipation and the input current reduce below their respective limiting thresholds before the TIMER pin reaches 3.9V, the 74  $\mu$ A current source is switched off, and  $C_T$  is discharged by the internal 2.4  $\mu$ A current sink ( $t_3$  in [Figure 2](#)). The in-rush limiting will no longer engage unless a current-limit condition occurs.

If the TIMER pin voltage reaches 3.9V before in-rush current limiting or power limiting ceases during  $t_2$ , a fault is declared and  $Q_1$  is turned off. See the [Fault Timer & Restart](#) section for a complete description of the fault mode.

The LM5064 will assert the **SMBA** pin after the operating voltage has exceeded the POR threshold to indicate that the volatile memory and device settings are in their default state. The **CONFIG\_PRESET** bit within the **MFR\_SPECIFIC\_17** register (E1h) indicates default configuration of warning thresholds and device operation and will remain high until a **CLEAR\_FAULTS** command is received.

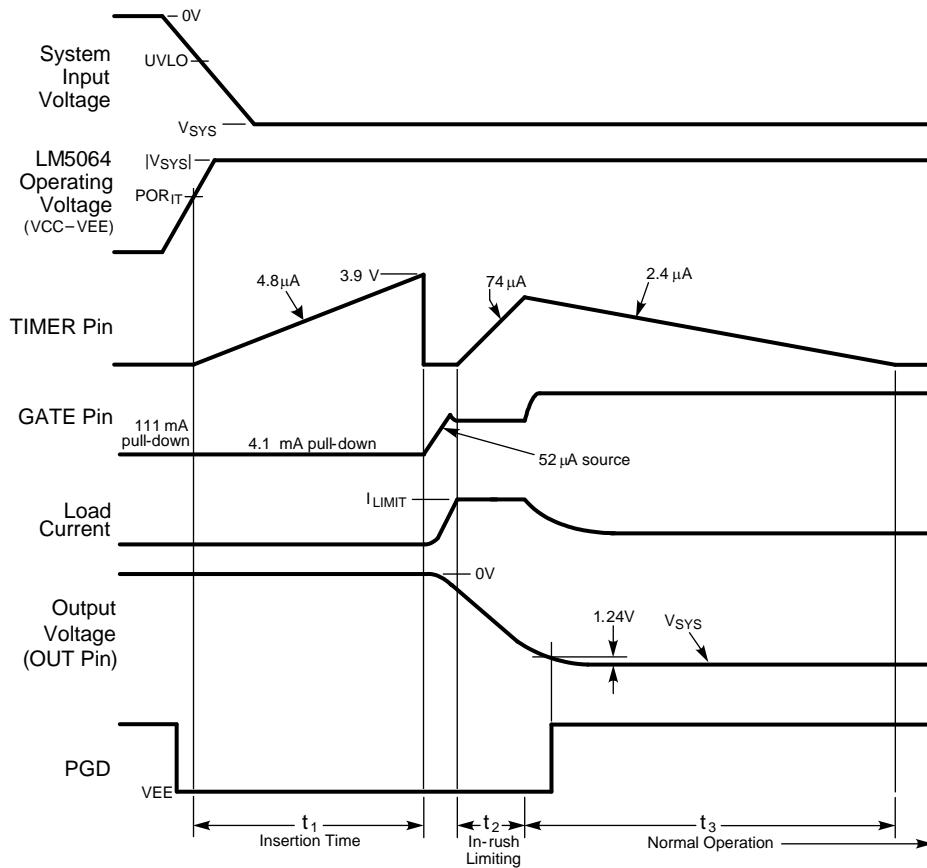


Figure 2. Power Up Sequence

## Gate Control

A current source provides the charge at the GATE pin to enhance the N-Channel MOSFET's gate ( $Q_1$ ). During normal operating conditions ( $t_3$  in Figure 2) the gate of  $Q_1$  is held charged by an internal 52  $\mu$ A current source. The GATE pin peak voltage is roughly 12.6V, which will force a  $V_{GS}$  across  $Q_1$  of 12.6V under normal operation. When the system voltage is initially applied, the GATE pin is held low by a 111 mA pull-down current. This helps prevent an inadvertent turn on of  $Q_1$  through its drain-gate capacitance as the applied system voltage increases.

During the insertion time ( $t_1$  in Figure 2), the GATE pin is held low by a 4.1 mA pull-down current. This maintains  $Q_1$  in the off-state until the end of  $t_1$ , regardless of the voltage on  $V_{SYS}$  or UVLO/EN. Following the insertion time, during  $t_2$  in Figure 2, the gate voltage of  $Q_1$  is modulated to keep the current or power dissipation level from exceeding the programmed levels. While in the current or power limiting mode, the TIMER pin capacitor is charging. If the current and power limiting cease before the TIMER pin reaches 3.9V, the TIMER pin capacitor then discharges, and the circuit begins normal operation. If the in-rush limiting condition persists such that the TIMER pin reached 3.9V during  $t_2$ , the GATE pin is then pulled low by the 4.1 mA pull-down current. The GATE pin is then held low until either a power up sequence is initiated (RETRY pin to VDD), an automatic retry is attempted (RETRY pin to VEE or floating), or a PMBus ON/OFF command is initiated. See the [Fault Timer & Restart](#) section. If the operating voltage falls below the UVLO threshold, or rises above the OVLO threshold, the GATE pin is pulled low by the 4.1 mA pull-down current to switch off  $Q_1$ .

## Current Limit

The current limit threshold is reached when the voltage across the sense resistor  $R_S$  (SENSE to VEE) exceeds the internal voltage limit of 26 mV or 50 mV depending on whether the CL pin is connected to VDD or VEE, respectively. In the current limiting condition, the GATE voltage is controlled to limit the current in MOSFET  $Q_1$ . While the current limit circuit is active, the fault timer is active as described in the [Fault Timer & Restart](#) section. If the load current falls below the current limit threshold before the end of the Fault Timeout Period, the LM5064 resumes normal operation. If the current limit condition persists for longer than the Fault Timeout Period set by  $C_T$ , the IIN OC Fault bit in the STATUS\_INPUT (7Ch) register, the INPUT bit in the STATUS\_WORD (79h) register, and IIN\_OC/PFET\_OP\_FAULT bit in the DIAGNOSTIC\_WORD (E1h) register will be toggled high and SMBA pin will be asserted. SMBA toggling can be disabled using the ALERT\_MASK (D8h) register. For proper operation, the  $R_S$  resistor value should be no higher than 200 mΩ. Higher values may create instability in the current limit control loop. The current limit threshold pin value may be overridden by setting appropriate bits in the DEVICE\_SETUP register (D9h).

## Circuit Breaker

If the load current increases rapidly (e.g., the load is short circuited), the current in the sense resistor ( $R_S$ ) may exceed the current limit threshold before the current limit control loop is able to respond. If the current exceeds 1.9x or 3.7x (CL = VEE) the current limit threshold,  $Q_1$  is quickly switched off by the 111 mA pull-down current at the GATE pin, and a Fault Timeout Period begins. When the voltage across  $R_S$  falls below the circuit breaker (CB) threshold, the 111 mA pull-down current at the GATE pin is switched off, and the gate voltage of  $Q_1$  is then determined by the current limit or the power limit functions. If the TIMER pin reaches 3.9V before the current limiting or power limiting condition ceases,  $Q_1$  is switched off by the 4.1 mA pull-down current at the GATE pin as described in the [Fault Timer & Restart](#) section. A circuit breaker event will cause the CIRCUIT\_BREAKER\_FAULT bit in the STATUS\_MFR\_SPECIFIC (80h) and DIAGNOSTIC\_WORD (E1h) registers to be toggled high, and SMBA pin will be asserted unless this feature is disabled using the ALERT\_MASK (D8h) register. The circuit breaker pin configuration may be overridden by setting appropriate bits in the DEVICE\_SETUP (D9h) register.

## Power Limit

An important feature of the LM5064 is the MOSFET power limiting. The power limit function can be used to maintain the maximum power dissipation of MOSFET  $Q_1$  within the device SOA rating. The LM5064 determines the power dissipation in  $Q_1$  by monitoring its drain-source voltage (OUT to SENSE), and the drain current through the  $R_S$  (SENSE to VEE). The product of the current and voltage is compared to the power limit threshold programmed by the resistor at the PWR pin. If the power dissipation reaches the limiting threshold, the GATE voltage is modulated to regulate the current in  $Q_1$ . While the power limiting circuit is active, the fault timer is active as described in the [Fault Timer & Restart](#) section. If the power limit condition persists for longer than the Fault Timeout Period set by the timer capacitor,  $C_T$ , the IIN OC Fault bit in the STATUS\_INPUT (7Ch) register, the INPUT bit in the STATUS\_WORD (79h) register, and the IIN\_OC/PFET\_OP\_FAULT bit in the DIAGNOSTIC\_WORD (E1h) register will be toggled high and SMBA pin will be asserted unless this feature is disabled using the ALERT\_MASK (D8h) register.

## Fault Timer & Restart

When the current limit or power limit threshold is reached during turn-on, or as a result of a fault condition, the gate-to-source voltage of  $Q_1$  is modulated to regulate the load current and power dissipation in  $Q_1$ . When either limiting function is active, a 74 μA fault timer current source charges the external capacitor ( $C_T$ ) at the TIMER pin as shown in [Figure 2](#) (Fault Timeout Period). If the fault condition subsides during the Fault Timeout Period before the TIMER pin reaches 3.9V, the LM5064 returns to the normal operating mode and  $C_T$  is discharged by the 1.5 mA current sink. If the TIMER pin reaches 3.9V during the Fault Timeout Period,  $Q_1$  is switched off by a 4.1 mA pull-down current at the GATE pin. The subsequent restart procedure then depends on the selected retry configuration.

If the RETRY pin is high (VDD), the LM5064 latches the GATE pin low at the end of the Fault Timeout Period.  $C_T$  is then discharged to VEE by the 2.4 μA fault current sink. The GATE pin is held low by the 4.1 mA pull-down current until a power up sequence is externally initiated by cycling the operating voltage (VCC-VEE), or momentarily pulling the UVLO/EN pin below its threshold with an open-collector or open-drain device as shown in [Figure 3](#). The voltage at the TIMER pin must be <0.3V for the restart procedure to be effective. The TIMER\_LATCHED\_OFF bit in the DIAGNOSTIC\_WORD (E1h) register will remain high while the latched off condition persists.

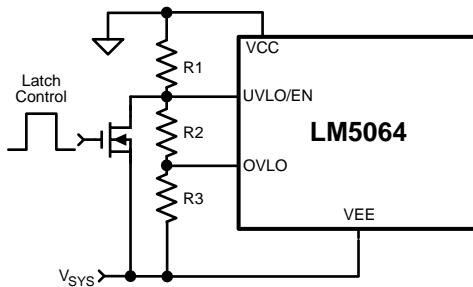


Figure 3. Latched Fault Restart Control

The LM5064 provides an automatic restart sequence which consists of the TIMER pin cycling between 3.9V and 1.2V eight times after the Fault Timeout Period, as shown in Figure 4. The period of each cycle is determined by the 74  $\mu$ A charging current, and the 2.4  $\mu$ A discharge current, and the value of the capacitor  $C_T$ . When the TIMER pin reaches 0.3V during the eighth high-to-low ramp, the 52  $\mu$ A current source at the GATE pin turns on  $Q_1$ . If the fault condition is still present, the Fault Timeout Period and the restart sequence repeat. The RETRY pin allows selecting no retries or infinite retries. Finer control of the retry behavior can be achieved through the DEVICE\_SETUP (D9h) register. Retry counts of 0, 1, 2, 4, 8, 16 or infinite may be selected by setting the appropriate bits in the DEVICE\_SETUP (D9h) register.

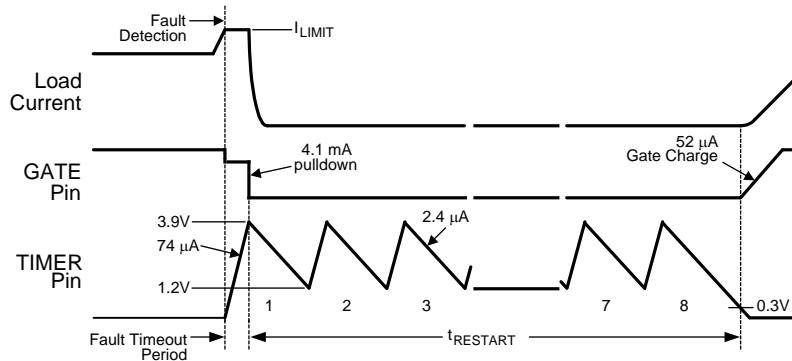


Figure 4. Restart Sequence

### Under-Voltage Lockout (UVLO)

The series pass MOSFET ( $Q_1$ ) is enabled when the input supply voltage ( $V_{SYS}$ ) is within the operating range defined by the programmable under-voltage lockout (UVLO) and over-voltage lockout (OVLO) levels. Typically, the UVLO level at  $V_{SYS}$  is set with a resistor divider (R1-R3) as shown in Figure 5. Referring to the Block Diagram when  $V_{SYS}$  is below the UVLO level, the internal 20  $\mu$ A current source at UVLO/EN is enabled, the current source at OVLO is off, and  $Q_1$  is held off by the 4.1 mA pull-down current at the GATE pin. As  $V_{SYS}$  is increased, raising the voltage at UVLO/EN above its threshold with respect to VEE, the 20  $\mu$ A current source at UVLO/EN is switched off, increasing the voltage at UVLO/EN, providing hysteresis for this threshold. With the UVLO/EN pin above its threshold,  $Q_1$  is switched on by the 52  $\mu$ A current source at the GATE pin if the insertion time delay has expired.

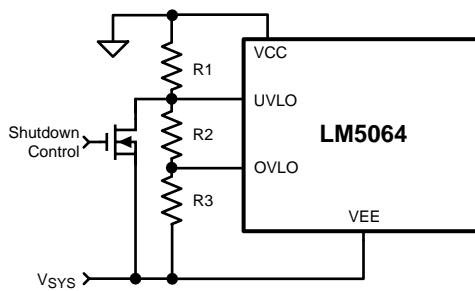
See the [Application Information](#) section for a procedure to calculate the values of the threshold setting resistors (R1-R3). The minimum possible UVLO level at  $V_{SYS}$  can be set by connecting the UVLO/EN pin to VCC. In this case  $Q_1$  is enabled after the insertion time when the operating voltage (VCC-VEE) reaches the POR threshold. After power up an UVLO condition will cause the INPUT bit in the STATUS\_WORD (79h) register, the VIN\_UV\_FAULT bit in the STATUS\_INPUT (7Ch) register, and the VIN\_UNDERVOLTAGE\_FAULT bit in the DIAGNOSTIC\_WORD (E1h) registers to be toggled high and SMBA pin will be pulled low unless this feature is disabled using the ALERT\_MASK (D8h) register.

## Over-Voltage Lockout (OVLO)

The series pass MOSFET ( $Q_1$ ) is enabled when the input supply voltage ( $V_{SYS}$ ) is within the operating range defined by the programmable under-voltage lockout (UVLO) and over-voltage lockout (OVLO) levels. If  $V_{SYS}$  raises the OVLO pin voltage above its threshold (2.47V above VEE),  $Q_1$  is switched off by the 4.1 mA pull-down current at the GATE pin, denying power to the load. When the OVLO pin is above its threshold, the internal 21  $\mu$ A current source at OVLO is switched on, raising the voltage at OVLO to provide threshold hysteresis. When  $V_{SYS}$  is reduced below the OVLO level  $Q_1$  is re-enabled. An OVLO condition will toggle the VIN\_OV\_FAULT bit in the STATUS\_INPUT (7Ch) register, the INPUT bit in the STATUS\_WORD (79h) register and the VIN\_OVERVOLTAGE\_FAULT bit in the DIAGNOSTIC\_WORD (E1h) register. The SMBA pin will be pulled low unless this feature is disabled using the ALERT\_MASK (D8h) register.

## Shutdown Control

The load current can be remotely switched off by taking the UVLO/EN pin below its threshold with an open collector or open drain device, as shown in [Figure 5](#). Upon releasing the UVLO/EN pin the LM5064 switches on the load current with in-rush current and power limiting.



**Figure 5. Shutdown Control**

## Power Good Pin

The Power Good output indicator pin (PGD) is connected to the drain of an internal N-channel MOSFET. An external pull-up resistor is required at PGD to an appropriate voltage to indicate the status to downstream circuitry. The off-state voltage at the PGD pin must be more positive than VEE, and can be up to 80V above VEE with transient capability to 100V. PGD is switched high at the end of the turn-on sequence when the voltage from OUT to SENSE (the external MOSFET's  $V_{DS}$ ) decreases below 1.24V. PGD switches low if the MOSFET's  $V_{DS}$  increases passed 2.5V, if the system input voltage goes below the UVLO threshold or above the OVLO threshold, or if a fault is detected. However, the PGD output cannot stay low when the operating voltage (VCC-VEE) is less than 2V.

## VDD Sub-Regulator

The LM5064 contains an internal linear sub-regulator which steps down the VCC voltage to generate a 4.9V rail (above VEE) used for powering low voltage circuitry. The VDD sub-regulator should be used as the pull-up supply for the CL, RETRY, ADR2, ADR1, ADR0 pins if they are to be tied high. It may also be used as the pull-up supply for the PGD and the SMBus signals (SDA, SCL, SMBA). The VDD sub-regulator is not designed to drive high currents. Careful consideration of internal power dissipation should be practiced when VDD is loaded with other integrated circuits. The VDD pin is current limited to 30 mA in order to protect the LM5064 in the event of a short. The sub-regulator requires a ceramic bypass capacitance (terminated to VEE) having a value of 1  $\mu$ F or greater to be placed as close to the VDD pin as the PCB layout allows.

## Remote Temperature Sensing

The LM5064 is designed to measure temperature remotely using an MMBT3904 NPN transistor. The base and collector of the MMBT3904 should be connected to the DIODE pin and the emitter to VEE. Place the MMBT3904 near the device that requires temperature sensing. If the temperature of the hot swap pass MOSFET,  $Q_1$ , is to be measured, the MMBT3904 should be placed as close to  $Q_1$  as the layout allows. The temperature is measured by means of a change in the diode voltage in response to a step in current supplied by the DIODE pin. The DIODE pin sources a constant 9.4  $\mu$ A but pulses 250  $\mu$ A once every millisecond in order to measure the diode temperature. Care must be taken in the PCB layout to keep the parasitic resistance between the DIODE pin and the MMBT3904 low so as not to degrade the measurement. Additionally, a small 1000 pF bypass capacitor should be placed in parallel with the MMBT3904 (collector to emitter) to reduce the effects of noise. The temperature can be read using the READ\_TEMPERATURE\_1 PMBus command (8Dh). The default limits of the LM5064 will cause SMBA pin to be pulled low if the measured temperature exceeds 125°C and will disable  $Q_1$  if the temperature exceeds 150°C. These thresholds can be reprogrammed via the PMBus interface using the OT\_WARN\_LIMIT (51h) and OT\_FAULT\_LIMIT (4Fh) commands. If the temperature measurement and protection capability of the LM5064 are not used, the DIODE pin should be connected to VEE.

Erroneous temperature measurements may result when the device input voltage is below the minimum operating voltage (10V) due to VREF dropping out below the nominal voltage (2.97V). At higher ambient temperatures, this measurement could read a value higher than the OT\_FAULT\_LIMIT, and will trigger a fault, disabling  $Q_1$ . In this case, the faults should be removed and the device reset by writing a 0h, followed by an 80h to the OPERATION (01h) register.

## Damaged MOSFET Detection

The LM5064 is able to detect whether the external MOSFET,  $Q_1$ , is damaged under certain conditions. If the voltage across the sense resistor exceeds 4 mV while the GATE voltage is low or the internal logic indicates that the GATE should be low, the EXT\_MOSFET\_SHORTED bit in the STATUS\_MFR\_SPECIFIC (80h) and DIAGNOSTIC\_WORD (E1h) registers will be toggled high and the SMBA pin will be asserted unless this feature is disabled using the ALERT\_MASK register (D8h). This method effectively determines whether  $Q_1$  is shorted because of damage present between the drain and gate and/or drain and source.

## Enabling/Disabling and Resetting

The output can be disabled at any time during normal operation by either pulling the UVLO/EN pin to below its threshold or the OVLO pin above its threshold, causing the GATE voltage to be forced low with a pull-down strength of 4.1 mA. Toggling the UVLO/EN pin will also reset the LM5064 from a latched-off state due to an over-current or over-power limit condition which has caused the maximum allowed number of retries to be exceeded. While the UVLO/EN or OVLO pins can be used to disable the output they have no effect on the volatile memory or address location of the LM5064. User stored values for address, device operation, and warning and fault levels programmed via the SMBus are preserved while the LM5064 is powered regardless of the state of the UVLO/EN and OVLO pins. The output may also be enabled or disabled by writing 80h or 0h to the OPERATION (01h) register. To re-enable after a fault, the fault condition should be cleared and the OPERATION (01h) register should be written with a 0h and then 80h.

The SMBus address of the LM5064 is captured based on the states (VEE, NC, VDD) of the ADR0, ADR1, and ADR2 pins during turn-on and is latched into a volatile register once VDD has exceeded its POR threshold of 4.1V. Reassigning or postponing the address capture is accomplished by holding the VREF pin to VEE. Pulling the VREF pin low will also reset the logic and erase the volatile memory of the LM5064. Once released, the VREF pin will charge up to its final value and the address will be latched into a volatile register once the voltage at the VREF exceeds 2.55V.

## APPLICATION INFORMATION

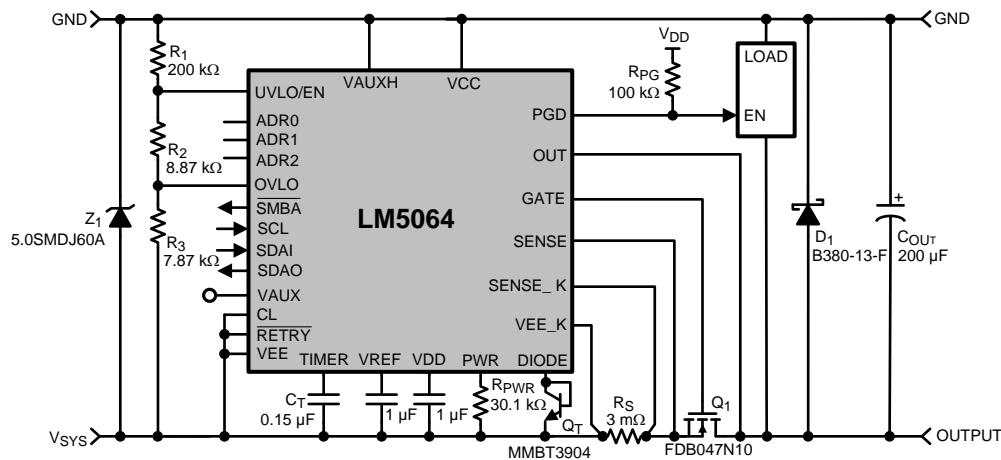


Figure 6. Typical Application Circuit

## DESIGN-IN PROCEDURE

Refer to [Figure 6](#) for a Typical Application Circuit. The following is a step-by-step procedure for hardware design of the LM5064. This procedure refers to section numbers that provide detailed information on the following design steps. The recommended design-in procedure is as follows:

**MOSFET Selection:** Determine the MOSFET based on breakdown voltage, current and power ratings.

**Current Limit,  $R_S$ :** Determine the current limit threshold ( $I_{LIM}$ ). This threshold must be higher than the normal maximum load current, allowing for tolerances in the current sense resistor value and the LM5064 Current Limit threshold voltage. Use [Equation 1](#) to determine the value for  $R_S$ .

**Power Limit Threshold:** Determine the maximum allowable power dissipation for the series pass MOSFET ( $Q_1$ ), using the device's SOA information. Use [Equation 2](#) to determine the value for  $R_{PWR}$ . Note that many MOSFET manufacturers do not accurately specify the device SOA so it is usually beneficial to choose a conservative value when selecting  $R_{PWR}$ .

**Turn-on Time and TIMER Capacitor,  $C_T$ :** Determine the value for the timing capacitor at the TIMER pin ( $C_T$ ) using [Equation 7](#) and [Equation 8](#). The fault timeout period ( $t_{FAULT}$ ) **MUST** be longer than the circuit's turn-on time. The turn-on time can be estimated using the equations in the [TURN-ON TIME](#) section, but should be verified experimentally. Review the resulting insertion time and the restart timing if retry is enabled.

**UVLO, OVLO:** Choose option A, B, C, or D from the [UVLO, OVLO](#) section to set the UVLO and OVLO thresholds and hysteresis. Use the procedure for the appropriate option to determine the resistor values at the UVLO/EN and OVLO pins.

## MOSFET SELECTION

It is recommended that the external MOSFET ( $Q_1$ ) selection is based on the following criteria:

- The  $BV_{DSS}$  rating should be greater than the maximum system voltage ( $V_{SYS}$ ), plus ringing and transients which can occur when the circuit card, or adjacent cards, are inserted or removed.
- The maximum continuous current rating should be based on the current limit threshold (for example,  $26 \text{ mV}/R_S$  for  $CL = VDD$ ), not the maximum load current, since the circuit can operate near the current limit threshold continuously.
- The Pulsed Drain Current spec ( $I_{DM}$ ) must be greater than the current threshold for the circuit breaker function ( $49/93/187 \text{ mV}/R_S$ , depending on  $CL$  and  $CB$  configuration).

- The SOA (Safe Operating Area) chart of the device, and the thermal properties, should be used to determine the maximum power dissipation threshold set by the  $R_{PWR}$  resistor. The programmed maximum power dissipation should have a reasonable margin from the maximum power defined by the MOSFET's SOA curve. If the device is set to infinitely retry, the MOSFET will be repeatedly stressed during fault restart cycles. The MOSFET manufacturer should be consulted for guidelines.

-  $R_{DS(on)}$  should be sufficiently low such that the power dissipation at maximum load current ( $I_{LIM}^2 \times R_{DS(on)}$ ) does not raise its junction temperature above the manufacturer's recommendation.

- The gate-to-source voltage provided by the LM5064 can be as high as 12.6V.  $Q_1$  must be able to tolerate this voltage for its  $V_{GS}$  rating. An additional zener diode can be added from GATE to VEE to lower this voltage and limit the peak  $V_{GS}$ .

### CURRENT LIMIT ( $R_s$ )

The LM5064 monitors the current in the external MOSFET  $Q_1$  by measuring the voltage across the sense resistor ( $R_s$ ), connected from SENSE to VEE. The required resistor value is calculated from:

$$R_s = \frac{V_{CL}}{I_{LIM}} \quad (1)$$

where  $I_{LIM}$  is the desired current limit threshold. If the voltage across  $R_s$  reaches  $V_{CL}$ , the current limit circuit modulates the gate of  $Q_1$  to regulate the current at  $I_{LIM}$ . While the current limiting circuit is active, the fault timer is active as described in the [Fault Timer & Restart](#) section. For proper operation,  $R_s$  must be less than 200 m $\Omega$ .

$V_{CL}$  can be set to either 26 mV or 50 mV via hardware and/or software. This setting defaults to use of CL pin which, when connected to VDD is 26 mV, or VEE is 50 mV. The value, when powered, can be set via the PMBus with the DEVICE\_SETUP (D9h) command, which defaults to the 26 mV setting.

Once the desired setting is known, calculate the shunt based on that input voltage and maximum current. While the maximum load current in normal operation can be used to determine the required power rating for resistor  $R_s$ , basing it on the current limit value provides a more reliable design since the circuit can operate near the current limit threshold continuously. The resistor's surge capability must also be considered since the circuit breaker threshold is 1.9 or 3.7 times the current limit threshold.

Connections from  $R_s$  to the LM5064 should be made using Kelvin techniques. In the suggested layout of [Figure 7](#) the small pads at the lower corners of the sense resistor connect only to the sense resistor terminals, and not to the traces carrying the high current. With this technique, only the voltage across the sense resistor is applied to SENSE\_K, SENSE, and VEE\_K, eliminating the voltage drop across the high current solder connections.

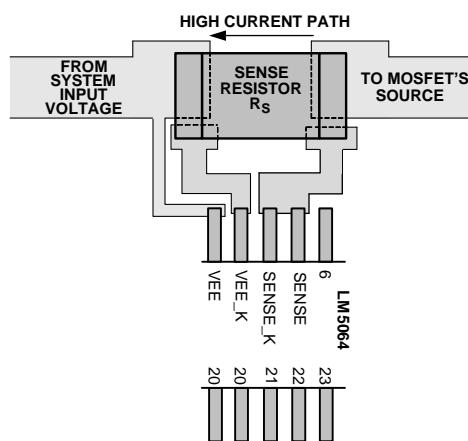


Figure 7. Sense Resistor Connections

## POWER LIMIT THRESHOLD

The LM5064 determines the power dissipation in the external MOSFET ( $Q_1$ ) by monitoring the drain current (the current in  $R_S$ ) and the  $V_{DS}$  of  $Q_1$  (OUT to SENSE pins). The resistor at the PWR pin ( $R_{PWR}$ ) sets the maximum power dissipation for  $Q_1$ , and is calculated from the following equation:

$$R_{PWR} = 1.25 \times 10^5 \times R_S \times P_{MOSFET(LIM)} \quad (2)$$

where  $P_{MOSFET(LIM)}$  is the desired power limit threshold for  $Q_1$ , and  $R_S$  is the current sense resistor described in the [CURRENT LIMIT \( \$R\_S\$ \)](#) section. For example, if  $R_S$  is  $3 \text{ m}\Omega$ ,  $V_{IN} = 48V$ , and the desired power limit threshold is  $80W$ ,  $R_{PWR}$  calculates to  $30.1 \text{ k}\Omega$  (standard 1% value). If  $Q_1$ 's power dissipation reaches the threshold  $Q_1$ 's gate is modulated to regulate the load current, keeping  $Q_1$ 's power from exceeding the threshold. For proper operation of the power limiting feature,  $R_{PWR}$  must be  $\leq 150 \text{ k}\Omega$ . While the power limiting circuit is active, the fault timer is active as described in the [Fault Timer & Restart](#) section. Typically, power limit is reached during startup, or if the output voltage falls due to a severe over-load or short circuit. The programmed maximum power dissipation should have a reasonable margin from the maximum power defined by the SOA chart, especially if retry is enabled, because the MOSFET will be repeatedly stressed during fault restart cycles. The MOSFET manufacturer should be consulted for guidelines. If the application does not require use of the power limit function the PWR pin can be left open. The accuracy of the power limit function at turn-on may degrade if a very low power dissipation limit is set. The reason for this caution is that the voltage across the sense resistor, which is monitored and regulated by the power limit circuit, is lowest at turn-on when the regulated current is at a minimum. The voltage across the sense resistor during power limit can be expressed as follows:

$$V_{SENSE} = I_{LIM} \times R_S = \frac{R_S \times P_{MOSFET(LIM)}}{V_{DS}} \quad (3)$$

where  $I_{LIM}$  is the current in  $R_S$ , and  $V_{DS}$  is the voltage across  $Q_1$ . For example, if the power limit is set at  $80W$  with  $R_S = 3 \text{ m}\Omega$ , and  $V_{DS} = 48V$  the sense resistor voltage calculates to  $5.0 \text{ mV}$ , which is comfortably regulated by the LM5064. However, if the power limit is set lower (e.g.,  $25W$ ), the sense resistor voltage calculates to  $1.6 \text{ mV}$ . At this low level noise and offsets within the LM5064 may degrade the power limit accuracy. To maintain accuracy, the sense resistor voltage should not be less than  $3 \text{ mV}$ .

## TURN-ON TIME

The output turn-on time depends on whether the LM5064 operates in current limit, or in both power limit and current limit, during turn-on.

**A) Turn-on with current limit only:** The current limit threshold ( $I_{LIM}$ ) is determined by the current sense resistor ( $R_S$ ). If the current limit threshold is less than the current defined by the power limit threshold at maximum  $V_{DS}$  the circuit operates only at the current limit threshold during turn-on. Referring to [Figure 8\(A\)](#), as the load current reaches  $I_{LIM}$ , the gate-to-source voltage is controlled at GATE to maintain the current at  $I_{LIM}$ . As the output voltage reaches its final value ( $V_{DS} \approx 0V$ ) the drain current reduces to its normal operating value. The time for the OUT pin voltage to transition from zero volts to  $V_{SYS}$  is equal to:

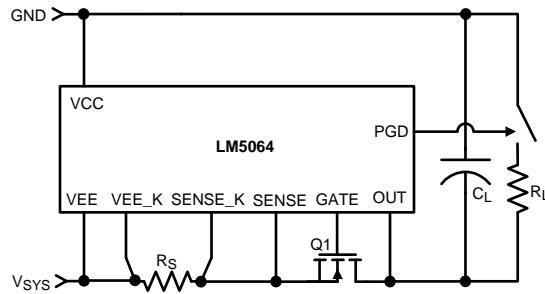
$$t_{on} = \frac{|V_{SYS}| \cdot C_L}{I_{LIM}} \quad (4)$$

where  $C_L$  is the load capacitance. For example, if  $V_{SYS} = -48V$ ,  $C_L = 200 \mu\text{F}$ , and  $I_{LIM} = 8.7A$ ,  $t_{on}$  calculates to  $1.1 \text{ ms}$ . The maximum instantaneous power dissipated in the MOSFET is  $418W$ . This calculation assumes the time from  $t_1$  to  $t_2$  in [Figure 9 \(A\)](#) is small compared to  $t_{on}$ , the load does not draw any current until after the output voltage has reached its final value, and PGD switches high ([Figure 8 \(A\)](#)). The Fault Timeout Period must be set longer than  $t_{on}$  to prevent a fault shut-down before the turn-on sequence is complete.

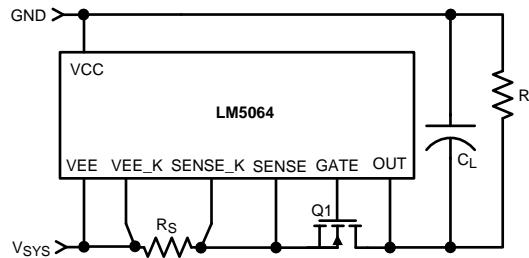
If the load draws current during the turn-on sequence ([Figure 8 \(B\)](#)), the turn-on time is longer than the above calculation, and is approximately equal to:

$$t_{on} = (R_L \times C_L) \times \ln \left[ \frac{(I_{LIM} \times R_L) - |V_{SYS}|}{(I_{LIM} \times R_L)} \right] \quad (5)$$

where  $R_L$  is the load resistance. The Fault Timeout Period must be set longer than  $t_{on}$  to prevent a fault shutdown before the turn-on sequence is complete.



A. No Load Current During Turn-On



B. Load Draws Current During Turn-On

Figure 8. Current During Turn-On

**B) Turn-On with Power Limit and Current Limit:** The maximum allowed power dissipation in Q<sub>1</sub> (P<sub>MOSFET(LIM)</sub>) is defined by the resistor at the PWR pin, and the current sense resistor R<sub>S</sub>. See the [POWER LIMIT THRESHOLD](#) section. If the current limit threshold (I<sub>LIM</sub>) is higher than the current defined by the power limit threshold at maximum V<sub>DS</sub> (P<sub>MOSFET(LIM)</sub>/|V<sub>SYS</sub>|) the circuit operates initially in the power limit mode when the V<sub>DS</sub> of Q<sub>1</sub> is high, and then transitions to current limit mode as the current increases to I<sub>LIM</sub> and V<sub>DS</sub> decreases. Assuming the load (R<sub>L</sub>) is not connected during turn-on, the time for the output voltage to reach its final value is approximately equal to:

$$t_{ON} = \frac{C_L \times V_{SYS}^2}{2 \times P_{MOSFET(LIM)}} + \frac{C_L \times P_{MOSFET(LIM)}}{2 \times I_{LIM}^2} \quad (6)$$

For example, if V<sub>SYS</sub> = -48V, C<sub>L</sub> = 200  $\mu$ F, I<sub>LIM</sub> = 8.7A, and P<sub>MOSFET(LIM)</sub> = 80W, t<sub>ON</sub> calculates to  $\approx$ 3.0 ms, and the initial current level (I<sub>P</sub>) is approximately 1.67A. The Fault Timeout Period must be set longer than t<sub>ON</sub>.

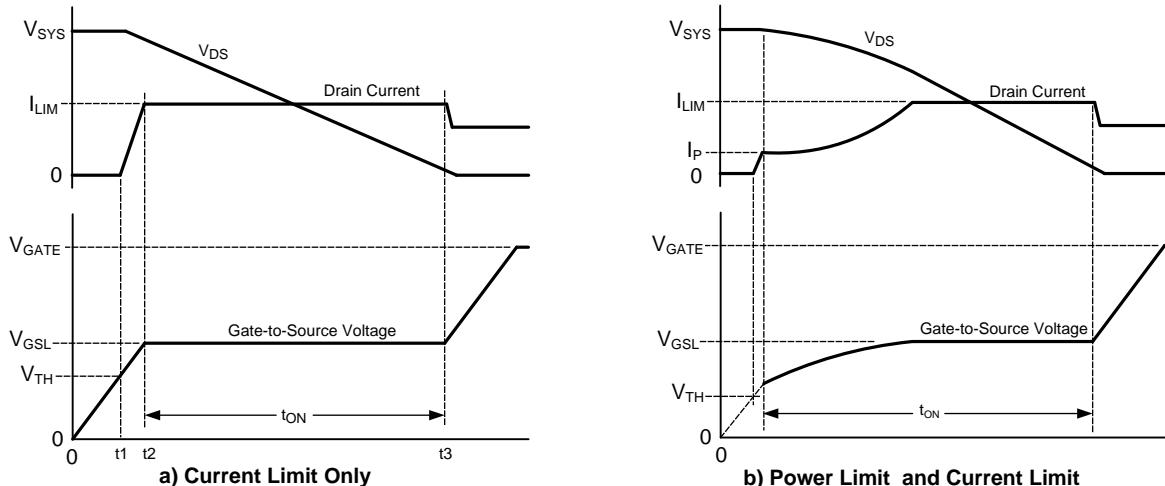


Figure 9. MOSFET Power Up Waveforms

## TIMER CAPACITOR, $C_T$

The TIMER pin capacitor ( $C_T$ ) sets the timing for the insertion time delay, fault timeout period, and the restart timing of the LM5064.

**A) Insertion Delay** -Upon applying the system voltage ( $V_{SYS}$ ) to the circuit, the external MOSFET ( $Q_1$ ) is held off during the insertion time ( $t_1$  in [Figure 2](#)) to allow ringing and transients at  $V_{SYS}$  to settle. Since each backplane's response to a circuit card plug-in is unique, the worst case settling time must be determined for each application. The insertion time starts when  $V_{SYS}$  reaches the POR threshold, at which time the internal 4.8  $\mu$ A current source charges  $C_T$  from 0V to 3.9V. The required capacitor value is calculated from:

$$C_T = \frac{t_1 \times 4.8 \mu\text{A}}{3.9\text{V}} = t_1 \times 1.2 \times 10^{-6} \quad (7)$$

For example, if the desired insertion delay is 125 ms,  $C_T$  calculates to 0.15  $\mu$ F. At the end of the insertion delay,  $C_T$  is quickly discharged by a 1.5 mA current sink.

**B) Fault Timeout Period** -During in-rush current limiting or upon detection of a fault condition where the current limit and/or power limit circuits regulate the current through  $Q_1$ , the fault timer current source (74  $\mu$ A) is switched on to charge  $C_T$ . The Fault Timeout Period is the time required for the TIMER pin voltage to reach 3.9V, at which time  $Q_1$  is switched off. The required capacitor value for the desired Fault Timeout Period  $t_{FAULT}$  is calculated from:

$$C_T = \frac{t_{FAULT} \times 74 \mu\text{A}}{3.9\text{V}} = t_{FAULT} \times 1.9 \times 10^{-5} \quad (8)$$

For example, if the desired Fault Timeout Period is 8 ms,  $C_T$  calculates to 0.15  $\mu$ F.  $C_T$  is discharged by the 2.4  $\mu$ A current sink at the end of the Fault Timeout Period. After the Fault Timeout Period, if  $\text{RETRY} = \text{VDD}$ , the LM5064 latches the GATE pin low until a power up sequence is initiated by external circuitry. When the Fault Timeout Period of the LM5064 expires, a restart sequence starts as described below (Restart Timing). During consecutive cycles of the restart sequence, the fault timeout period is shorter than the initial fault time out period described above by approximately 8% since the voltage at the TIMER pin starts ramping up from 0.3V rather than VEE.

Since the LM5064 normally operates in power limit and/or current limit during a power up sequence, the Fault Timeout Period **MUST** be longer than the time required for the output voltage to reach its final value. See the [TURN-ON TIME](#) section.

**C) Restart Timing** For the LM5064, after the Fault Timeout Period described above,  $C_T$  is discharged by the 2.4  $\mu$ A current sink to 1.2V. The TIMER pin then cycles through seven additional charge/discharge cycles between 1.2V and 3.9V as shown in [Figure 4](#). The restart time ends when the TIMER pin voltage reaches 0.3V during the final high-to-low ramp. The restart time, after the Fault Timeout Period, is equal to:

$$t_{RESTART} = C_T \times \left[ \frac{7 \times 2.7\text{V}}{2.4 \mu\text{A}} + \frac{7 \times 2.7\text{V}}{74 \mu\text{A}} + \frac{3.6\text{V}}{2.4 \mu\text{A}} \right] \quad (9)$$

$$= C_T \times 9.6 \times 10^6 \quad (10)$$

For example, if  $C_T = 0.15 \mu\text{F}$ ,  $t_{RESTART} = 1.4$  seconds. At the end of the restart time,  $Q_1$  is switched on. If the fault is still present, the fault timeout and restart sequence repeats. The on-time duty cycle of  $Q_1$  is approximately 0.5% in this mode.

## UVLO, OVLO

By programming the UVLO and OVLO thresholds the LM5064 enables the series pass device ( $Q_1$ ) when the input supply voltage ( $V_{SYS}$ ) is within the desired operational range. If  $V_{CC}$  is below the UVLO threshold, or above the OVLO threshold,  $Q_1$  is switched off, denying power to the load. Hysteresis is provided for each threshold.

**Option A:** The configuration shown in Figure 10 requires three resistors (R1-R3) to set the thresholds.

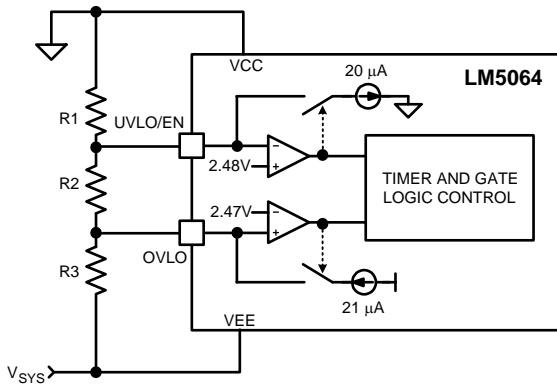


Figure 10. UVLO and OVLO Thresholds Set By R1-R3

The procedure to calculate the resistor values is as follows:

- Choose the upper UVLO threshold ( $V_{UVH}$ ), and the lower UVLO threshold ( $V_{UVL}$ ).
- Choose the upper OVLO threshold ( $V_{OVH}$ ).
- The lower OVLO threshold ( $V_{OVL}$ ) cannot be chosen in advance in this case, but is determined after the values for R1-R3 are determined. If  $V_{OVL}$  must be accurately defined in addition to the other three thresholds, see **Option B** below. The resistors are calculated as follows:

$$R1 = \frac{V_{UVH} - V_{UVL}}{20 \mu A} = \frac{V_{UV(HYS)}}{20 \mu A} \quad (11)$$

$$R3 = \frac{R1 \times V_{UVL} \times 2.47V}{V_{OVH} \times (V_{UVL} - 2.48V)} \quad (12)$$

$$R2 = \frac{2.48V \times R1}{V_{UVL} - 2.48V} - R3 \quad (13)$$

The lower OVLO threshold is calculated from:

$$V_{OVL} = \left[ (R1 + R2) \times \left( \frac{2.47V}{R3} \right) - 21 \mu A \right] + 2.47V \quad (14)$$

As an example, assume the application requires the following thresholds:  $V_{UVH} = 36V$ ,  $V_{UVL} = 32V$ ,  $V_{OVH} = 60V$ .

$$R1 = \frac{36V - 32V}{20 \mu A} = \frac{4V}{20 \mu A} = 200k \quad (15)$$

$$R3 = \frac{R1 \times 32V \times 2.47V}{60V \times (32V - 2.48V)} = 8.93k\Omega \quad (16)$$

$$R2 = \frac{2.48V \times R1}{32V - 2.48V} - R3 = 7.87 k\Omega \quad (17)$$

Using standard values of  $R1 = 200 k\Omega$ ,  $R2 = 8.87 k\Omega$ , and  $R3 = 7.87 k\Omega$ , the lower OVLO threshold calculates to 56V, and the OVLO hysteresis is 4.4V. Note that the OVLO hysteresis is always slightly greater than the UVLO hysteresis in this configuration. When the R1-R3 resistor values are known, the threshold voltages and hysteresis are calculated from the following:

$$V_{UVH} = 2.48V + R1 \times \left( \frac{2.48V}{R2 + R3} + 20 \mu A \right) \quad (18)$$

$$V_{UVL} = \frac{2.48V \times (R1 + R2 + R3)}{R2 + R3} \quad (19)$$

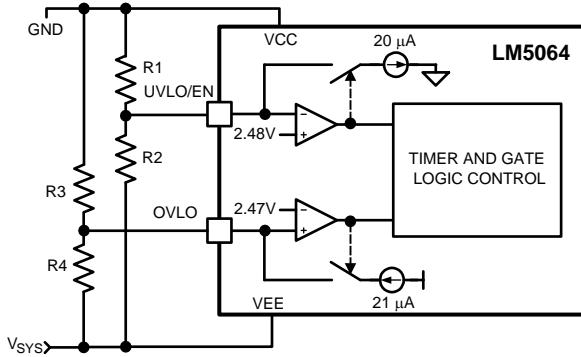
$$V_{UV(HYS)} = R1 \times 20 \mu A \quad (20)$$

$$V_{OVH} = \frac{2.47V \times (R1 + R2 + R3)}{R3} \quad (21)$$

$$V_{OVL} = \left( \frac{2.47V}{R3} - 21 \mu A \right) \times (R1 + R2) + 2.47V \quad (22)$$

$$V_{OV(HYS)} = (R1 + R2) \times 21 \mu A \quad (23)$$

**Option B:** If all four thresholds must be accurately defined, the configuration in [Figure 11](#) can be used.



**Figure 11. Programming the Four Thresholds**

The four resistor values are calculated as follows: - Choose the upper and lower UVLO thresholds ( $V_{UVH}$ ) and ( $V_{UVL}$ ).

$$R1 = \frac{V_{UVH} - V_{UVL}}{20 \mu A} = \frac{V_{UV(HYS)}}{20 \mu A} \quad (24)$$

$$R2 = \frac{2.48V \times R1}{(V_{UVL} - 2.48V)} \quad (25)$$

- Choose the upper and lower OVLO threshold ( $V_{OVH}$ ) and ( $V_{OVL}$ ).

$$R3 = \frac{V_{OVH} - V_{OVL}}{21 \mu A} = \frac{V_{OV(HYS)}}{21 \mu A} \quad (26)$$

$$R4 = \frac{2.47V \times R3}{(V_{OVH} - 2.47V)} \quad (27)$$

As an example, assume the application requires the following thresholds:  $V_{UVH} = 36V$ ,  $V_{UVL} = 32V$ ,  $V_{OVH} = 60V$ , and  $V_{OVL} = 56V$ . Therefore  $V_{UV(HYS)} = 4V$ , and  $V_{OV(HYS)} = 4V$ . The resistor values are:

$$R1 = 200 \text{ k}\Omega, R2 = 16.8 \text{ k}\Omega$$

$$R3 = 190 \text{ k}\Omega, R4 = 8.2 \text{ k}\Omega$$

When the R1-R4 resistor values are known, the threshold voltages and hysteresis are calculated from the following:

$$V_{UVH} = 2.48V + \left[ R1 \times \left( \frac{2.48V}{R2} + 20 \mu A \right) \right] \quad (28)$$

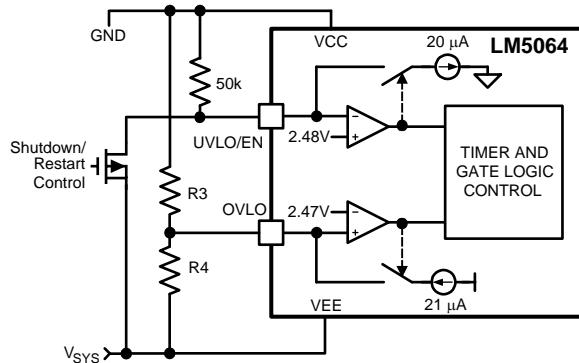
$$V_{UVL} = \frac{2.48V \times (R1 + R2)}{R2} \quad (29)$$

$$V_{UV(HYS)} = R1 \times 20 \mu A \quad (30)$$

$$V_{OVH} = \frac{2.47V \times (R3 + R4)}{R4} \quad (31)$$

$$V_{OVL} = 2.47V + \left[ R3 \times \left( \frac{2.47V}{R4} - 21 \mu A \right) \right] \quad (32)$$

**Option C:** The minimum UVLO level is obtained by connecting the UVLO/EN pin to VCC as shown in [Figure 12](#).  $Q_1$  is switched on when the VCC-VEE voltage reaches the  $PORE_{EN}$  threshold ( $\approx 8.7V$ ). The OVLO thresholds are set using R3, R4. Their values are calculated using the procedure in [Option B](#).

Figure 12. UVLO/EN = POR<sub>EN</sub>

**Option D:** The OVLO function can be disabled by connecting the OVLO pin to VEE. The UVLO thresholds are set as described in **Option B** or **Option C**.

#### POWER GOOD PIN (PGD)

When the Q<sub>1</sub> V<sub>DS</sub> voltage is below its threshold, the internal pull-down acting on the PGD pin is disabled, allowing PGD to rise to V<sub>PGD</sub> through the pull-up resistor, R<sub>PG</sub>, as shown in Figure 13. The pull-up voltage (V<sub>PGD</sub>) can be as high as 80V, and can be higher or lower than the voltages at VCC and OUT. VDD is a convenient choice for V<sub>PGD</sub> as it allows interface to low voltage logic and avoids glitching on PGD during power up. If a delay is required at PGD, suggested circuits are shown in Figure 14. In Figure 14(A), capacitor C<sub>PG</sub> adds delay to the rising edge, but not to the falling edge. In Figure 14(B), the rising edge is delayed by R<sub>PG1</sub> + R<sub>PG2</sub> and C<sub>PG</sub>, while the falling edge is delayed a lesser amount by R<sub>PG2</sub> and C<sub>PG</sub>. Adding a diode across R<sub>PG2</sub> (Figure 14 (C)) allows for equal delays at the two edges, or a short delay at the rising edge and a long delay at the falling edge.

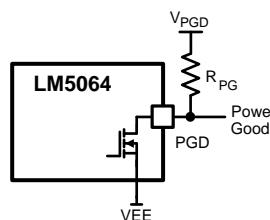


Figure 13. Power Good Output

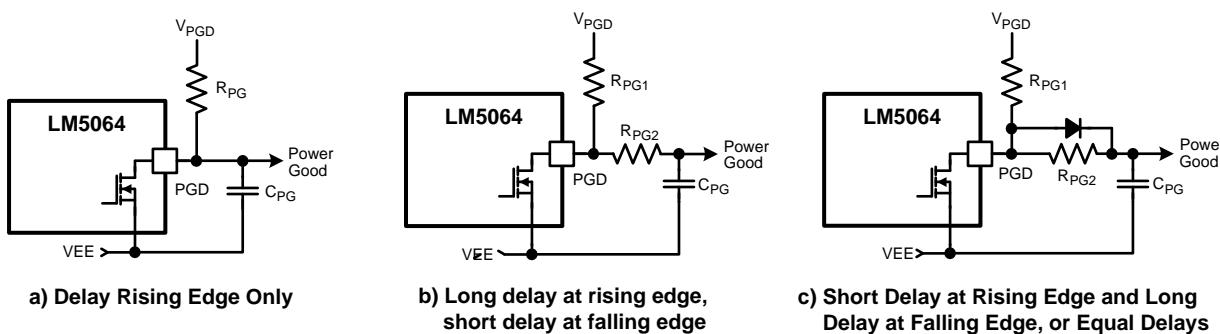
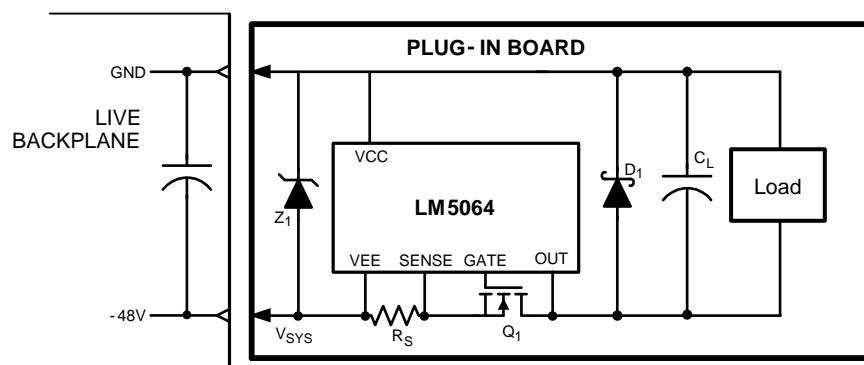


Figure 14. Adding Delay to the Power Good Output Pin

## SYSTEM CONSIDERATIONS

Continued proper operation of the LM5064 hot swap circuit requires a voltage clamping element present on the supply side of the connector into which the hot swap circuit is plugged in. A TVS (Transient Voltage Suppressor) is ideal, as depicted in [Figure 15](#) as  $Z_1$ . The TVS is necessary to absorb the voltage transient generated whenever the hot swap circuit shuts off the load current. If the TVS is not present, inductance in the supply lines will generate a voltage transient at shutdown which can exceed the absolute maximum rating of the LM5064, resulting in its destruction. For low current solutions ( $<2A$ ), a capacitor may be sufficient to limit the voltage surge, however this comes at the expense of input surge current on card insertion.

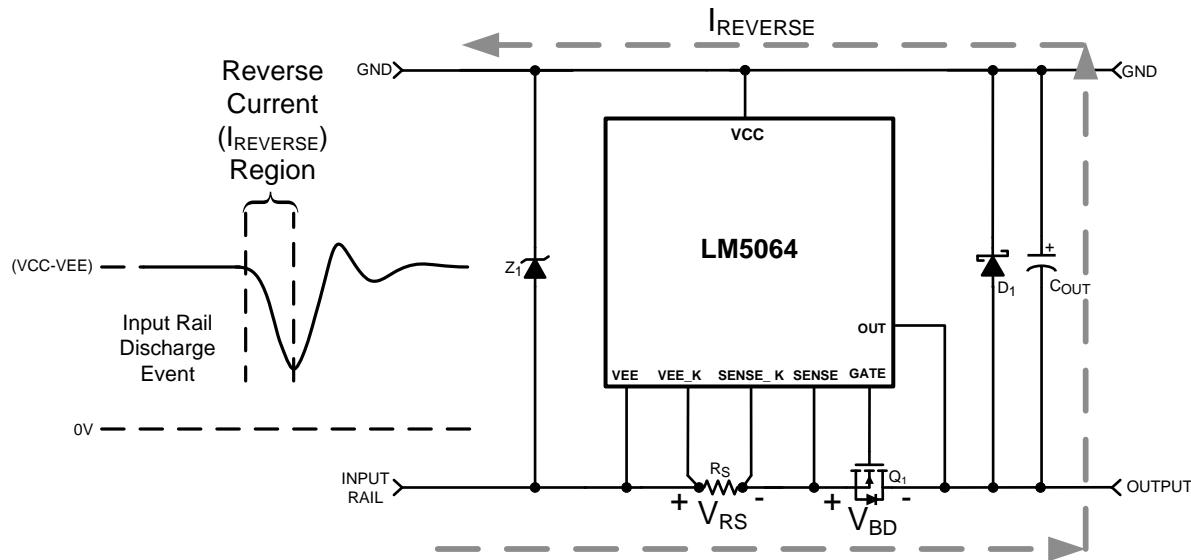
If the load powered by the LM5064 hot swap circuit has inductive characteristics, a Schottky diode ( $D_1$ ) is required across the LM5064's output, along with some load capacitance ( $C_L$ ). The capacitance and the diode are necessary to limit the negative excursion at the OUT pin when the load current is shut off. If the OUT pin transitions more than 0.3V negative the LM5064 can be permanently damaged. See [Figure 15](#).



**Figure 15. Output Diode Required for Inductive Loads**

## System Considerations During Surge Events

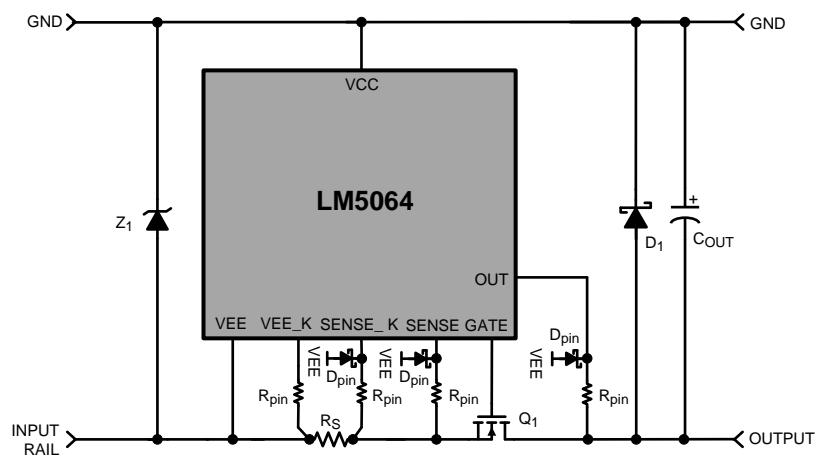
The control MOSFET,  $Q_1$ , has a body-diode, illustrated in [Figure 16](#), where current can freely flow in the reverse direction. The most common cause of a reverse current is a discharge event at the input of the hot-swap circuit when the output capacitance discharges to the input. Normally, reverse current flow presents no issue for hot-swap devices during events such as shutdown and minor input power perturbations. However, extreme situations such as high energy lighting surge line disturbances can expose the hot-swap circuit to pulses of ultra fast - high amplitude reverse currents. It is common to observe current amplitudes on the order of 1000A in these situations. [Figure 16](#) illustrates what an extreme input discharge event may look like and how it affects the circuit.



As the input dips, the output capacitor discharges causing a transient reverse current flow.

**Figure 16. Differential Voltage Across Sense Resistor**

Figure 16 shows how the induced reverse current spike causes a differential voltage across the sense resistor,  $V_{RS}$ , and the  $Q_1$  body-diode,  $V_{BD}$ . The transient reverse current,  $I_{REVERSE}$ , is approximately equal to  $I_{REVERSE} = C_{OUT} \times dV_{IN}/dt$  because the output capacitor is discharged through the input. Faster discharge rates ( $dV_{IN}/dt$ ) will induce larger  $I_{REVERSE}$  currents. If  $I_{REVERSE}$  is extremely high, it can cause a large negative voltage at the SENSE\_K, SENSE, and OUT pins with respect to the VEE pin of the LM5064. If the negative absolute maximum voltage rating is greatly exceeded, harmful currents can flow into the affected pins. Series pin resistors can be implemented to limit the pin current caused by the negative voltage excursion. Schottky diodes may also be implemented to completely clamp the voltage at these pins. Figure 17 illustrates this.



Series resistors are used to limit harmful negative pin currents and schottky diodes are used to clamp the voltage at each pin.

**Figure 17. Schottky Diodes Used to Clamp Pin Voltage**

A typical value of  $R_{pin}$  can be  $22\Omega$  to effectively limit the pin current during extreme negative voltage spikes. If schottky diodes are used, they only need to be applied to SENSE\_K, SENSE, and OUT. Each schottky diode return pin should be coupled closely with the VEE plane to provide the most effective clamping. The schottky diode at OUT should be able to withstand at least 100V. VEE\_K needs a series resistor even though it's not subjected to negative voltage spikes in order to balance the differential current sense voltage signal. Protecting the SENSE\_K, SENSE, and OUT pins from negative voltage spikes will facilitate a robust hot-swap circuit and smooth operation during extreme reverse current surge events.

## PC BOARD GUIDELINES

The following guidelines should be followed when designing the PC board for the LM5064:

- Place the LM5064 close to the board's input connector to minimize trace inductance from the connector to the MOSFET ( $Q_1$ ).
- Place a TVS ( $Z_1$ ), directly adjacent to the VCC and VEE pins of the LM5064 to help minimize voltage transients which may occur on the input supply line. The TVS should be chosen such that the peak  $V_{SYS}$  is just lower the TVS reverse-bias voltage. Transients of 20 volts or greater over the nominal input voltage can easily occur when the load current is shut off. A small capacitor may be sufficient for low current sense applications ( $I < 2A$ ). It is recommended to test the  $V_{SYS}$  input voltage transient performance of the circuit by current limiting or shorting the load and measuring the peak input voltage transient.
- Place a  $1\ \mu F$  ceramic capacitor as close as possible to VREF pin.
- Place a  $1\ \mu F$  ceramic capacitor as close as possible to VDD pin.
- Minimize the inductance between the SENSE, SENSE\_K, VEE\_K, and VEE pins. There are anti-parallel diodes between these pins so any voltage greater than 0.3V in either polarity will cause significant current flow through the diodes, which can result in device failure. Do not place any resistors between these nodes.
- Minimize the impedance between the VEE\_K and SENSE\_K pins. There are anti-parallel diodes between these pins so any voltage greater than 0.3V in either polarity will cause significant current flow through the diodes, which can result in device failure.
- The sense resistor ( $R_S$ ) should be placed close to the LM5064. A trace should connect the VEE source pin and OUT drain pad of  $Q_1$  to the sense resistor to VEE\_K and SENSE\_K pins, respectively. Connect  $R_S$  using the Kelvin techniques shown in [Figure 7](#).
- The high current path from the board's input to the load (via  $Q_1$ ), and the return path, should be parallel and close to each other to minimize loop inductance.
- The termination connections for the various components around the LM5064 should be connected directly to each other, and to the LM5064's VEE pin connection, and then connected to  $V_{SYS}$  at one point. Do not connect the various component terminations to each other through the high current  $V_{SYS}$  line.
- Provide adequate thermal sinking for the series pass device ( $Q_1$ ) to help reduce stresses during turn-on and turn-off.
- The board's edge connector can be designed such that the LM5064 detects via the UVLO/EN pin that the board is being removed, and responds by turning off the load before the supply voltage is disconnected. For example, in [Figure 18](#), the voltage at the UVLO/EN pin goes to VEE before  $V_{SYS}$  is removed from the LM5064 as a result of the shorter edge connector pin. When the board is inserted into the edge connector, the system voltage is applied to the LM5064's  $V_{SYS}$  pin before the UVLO voltage is taken high, thereby allowing the LM5064 to turn on the output in a controlled fashion.

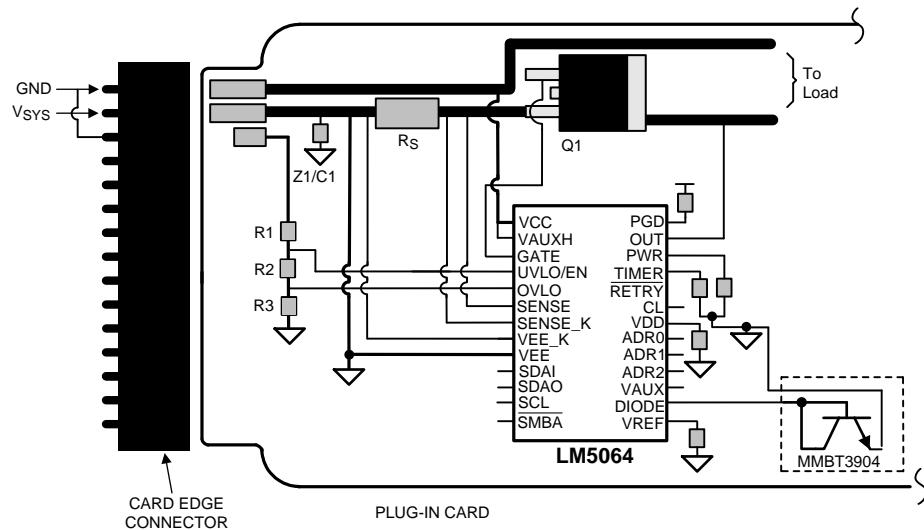


Figure 18. Recommended Board Connector Design

## PMBUS™ COMMAND SUPPORT

The device features an SMBus interface that allows the use of PMBus commands to set warn levels, error masks, and get telemetry on  $V_{IN}$  ( $V_{IN} = VAUXH = V_{VCC} - V_{VEE}$ ),  $V_{OUT}$  ( $V_{OUT} = V_{VCC} - V_{VOUT}$ ),  $I_{IN}$ ,  $V_{AUX}$ , and  $P_{IN}$ . The supported PMBus commands are shown in [Table 1](#).

**Table 1. Supported PMBus Commands**

| Code | Name                                     | Function  | R/W       | Number Of Data Bytes | Default Value                                      |
|------|--|---|-----------|----------------------|--|
| 01h  | OPERATION                                | Retrieves or stores the operation status.                                     | R/W       | 1                    | 80h  |
| 03h  | CLEAR_FAULTS                             | Clears the status registers and re-arms the Black Box registers for updating. | Send Byte | 0                    |  |
| 19h  | CAPABILITY                               | Retrieves the device capability.  | R         | 1                    | B0h  |
| 43h  | VOUT_UV_WARN_LIMIT                       | Retrieves or stores output under-voltage warn limit threshold.                | R/W       | 2                    | 0000h  |
| 4Fh  | OT_FAULT_LIMIT                           | Retrieves or stores over-temperature fault limit threshold.                   | R/W       | 2                    | 0960h (150°C)                                      |
| 51h  | OT_WARN_LIMIT                            | Retrieves or stores over-temperature warn limit threshold.                    | R/W       | 2                    | 07D0h (125°C)                                      |
| 57h  | VIN_OV_WARN_LIMIT                        | Retrieves or stores input over-voltage warn limit threshold.                  | R/W       | 2                    | 0FFFh  |
| 58h  | VIN_UV_WARN_LIMIT                        | Retrieves or stores input under-voltage warn limit threshold.                 | R/W       | 2                    | 0000h  |
| 78h  | STATUS_BYTE                              | Retrieves information about the parts operating status.                       | R         | 1                    | 49h  |
| 79h  | STATUS_WORD                              | Retrieves information about the parts operating status.                       | R         | 2                    | 3849h  |
| 7Ah  | STATUS_VOUT                              | Retrieves information about output voltage status.                            | R         | 1                    | 00h  |
| 7Ch  | STATUS_INPUT                             | Retrieves information about input status.                                     | R         | 1                    | 10h  |
| 7Dh  | STATUS_TEMPERATURE                       | Retrieves information about temperature status.                               | R         | 1                    | 00h  |
| 7Eh  | STATUS_CML                               | Retrieves information about communications status.                            | R         | 1                    | 00h  |
| 80h  | STATUS_MFR_SPECIFIC                      | Retrieves information about circuit breaker and MOSFET shorted status.        | R         | 1                    | 10h  |
| 88h  | READ_VIN                                 | Retrieves input voltage measurement.  | R         | 2                    | 0000h  |
| 8Bh  | READ_VOUT                                | Retrieves output voltage measurement.   | R         | 2                    | 0000h  |
| 8Dh  | READ_TEMPERATURE_1                       | Retrieves temperature measurement.  | R         | 2                    | 0190h  |
| 99h  | MFR_ID                                   | Retrieves manufacturer ID in ASCII characters (NSC).                          | R         | 3                    | 4Eh<br>53h<br>43h                                  |
| 9Ah  | MFR_MODEL                                | Retrieves Part number in ASCII characters. (LM5064\0\0).                      | R         | 8                    | 4Ch<br>4Dh<br>35h<br>30h<br>36h<br>36h<br>0h<br>0h |
| 9Bh  | MFR_REVISION                             | Retrieves part revision letter/number in ASCII (e.g., AA).                    | R         | 2                    | 41h<br>41h   |
| D0h  | MFR_SPECIFIC_00<br>READ_VAUX             | Retrieves auxiliary voltage measurement.                                      | R         | 2                    | 0000h  |
| D1h  | MFR_SPECIFIC_01<br>MFR_READ_IIN          | Retrieves input current measurement.  | R         | 2                    | 0000h  |
| D2h  | MFR_SPECIFIC_02<br>MFR_READ_PIN          | Retrieves input power measurement.  | R         | 2                    | 0000h  |
| D3h  | MFR_SPECIFIC_03<br>MFR_IIN_OC_WARN_LIMIT | Retrieves or stores input current limit warn threshold.                       | R/W       | 2                    | 0FFFh  |
| D4h  | MFR_SPECIFIC_04<br>MFR_PIN_OP_WARN_LIMIT | Retrieves or stores input power limit warn threshold.                         | R/W       | 2                    | 0FFFh  |
| D5h  | MFR_SPECIFIC_05<br>READ_PIN_PEAK         | Retrieves measured peak input power measurement.                              | R         | 2                    | 0000h  |

**Table 1. Supported PMBus Commands (continued)**

| Code | Name                                    | Function  | R/W       | Number Of Data Bytes | Default Value                                      |
|------|---|---|-----------|----------------------|--|
| D6h  | MFR_SPECIFIC_06<br>CLEAR_PIN_PEAK       | Resets the contents of the peak input power register to zero.   | Send Byte | 0                    |  |
| D7h  | MFR_SPECIFIC_07<br>GATE_MASK            | Allows the user to disable MOSFET gate shutdown for various fault conditions.                                       | R/W       | 1                    | 0000h  |
| D8h  | MFR_SPECIFIC_08<br>ALERT_MASK           | Retrieves or stores user SMBA fault mask.   | R/W       | 2                    | 0820h  |
| D9h  | MFR_SPECIFIC_09<br>DEVICE_SETUP         | Retrieves or stores information about number of retry attempts.   | R/W       | 1                    | 0000h  |
| DAh  | MFR_SPECIFIC_10<br>BLOCK_READ           | Retrieves most recent diagnostic and telemetry information in a single transaction.                                 | R         | 12                   | 0190h<br>0000h<br>0000h<br>0000h<br>0000h<br>0000h |
| DBh  | MFR_SPECIFIC_11<br>SAMPLES_FOR_AVG      | Exponent value AVGN for number of samples to be averaged ( $N = 2^{AVGN}$ ), range = 00h to 0Ch .                   | R/W       | 1                    | 00h  |
| DCh  | MFR_SPECIFIC_12<br>READ_AVG_VIN         | Retrieves averaged input voltage measurement.   | R         | 2                    | 0000h  |
| DDh  | MFR_SPECIFIC_13<br>READ_AVG_VOUT        | Retrieves averaged output voltage measurement.  | R         | 2                    | 0000h  |
| DEh  | MFR_SPECIFIC_14<br>READ_AVG_IIN         | Retrieves averaged input current measurement.   | R         | 2                    | 0000h  |
| DFh  | MFR_SPECIFIC_15<br>READ_AVG_PIN         | Retrieves averaged input power measurement.   | R         | 2                    | 0000h  |
| E0h  | MFR_SPECIFIC_16<br>BLACK_BOX_READ       | Captures diagnostic and telemetry information which are latched when the first SMBA event after faults are cleared. | R         | 12                   | 0000h<br>0000h<br>0000h<br>0000h<br>0000h<br>0000h |
| E1h  | MFR_SPECIFIC_17<br>DIAGNOSTIC_WORD_READ | Manufacturer-specific parallel of the STATUS_WORD to convey all FAULT/WARN data in a single transaction.            | R         | 2                    | 08E0h  |
| E2h  | MFR_SPECIFIC_18<br>AVG_BLOCK_READ       | Retrieves most recent average telemetry and diagnostic information in a single transaction.                         | R         | 12                   | 0000h<br>0000h<br>0000h<br>0000h<br>0000h<br>0000h |

## STANDARD PMBUS COMMANDS

### OPERATION (01h)

The OPERATION command is a standard PMBus command that controls the MOSFET switch. This command may be used to switch the MOSFET ON and OFF under host control. It is also used to re-enable the MOSFET after a fault triggered shutdown. Writing an OFF command, followed by an ON command, will clear all faults and re-enable the device. Writing only an ON after a fault-triggered shutdown will not clear the fault registers or re-enable the device. The OPERATION command is issued with the write byte protocol.

**Table 2. Recognized OPERATION Command Values**

| Value | Meaning    | Default |
|-------|------------|---------|
| 80h   | Switch ON  | 80h     |
| 00h   | Switch OFF | n/a     |

### CLEAR FAULTS (03h)

The CLEAR\_FAULTS command is a standard PMBus command that resets all stored warning and fault flags and the SMBA signal. If a fault or warning condition still exists when the CLEAR\_FAULTS command is issued, the SMBA signal may not clear or will re-assert almost immediately. Issuing a CLEAR\_FAULTS command will not cause the MOSFET to switch back on in the event of a fault turnoff - that must be done by issuing an OPERATION command after the fault condition is cleared. This command uses the PMBus send byte protocol.

### CAPABILITY (19h)

The CAPABILITY command is a standard PMBus command that returns information about the PMBus functions supported by the LM5064. This command is read with the PMBus read byte protocol.

**Table 3. CAPABILITY Register**

| Value | Meaning  | Default |
|-------|--|---------|
| B0h   | Supports Packet Error Check, 400Kbits/sec,<br>Supports SMBus Alert | B0h     |

### VOUT\_UV\_WARN\_LIMIT (43h)

The VOUT\_UV\_WARN\_LIMIT command is a standard PMBus command that allows configuring or reading the threshold for the VOUT under-voltage Warning detection. Reading and writing to this register should use the coefficients shown in [Table 41](#). Accesses to this command should use the PMBus read or write word protocol. If the measured value of VOUT falls below the value in this register, VOUT UV Warn flags are set and the SMBA signal is asserted.

**Table 4. VOUT\_UV\_WARN\_LIMIT Register**

| Value      | Meaning  | Default          |
|------------|--|------------------|
| 1h – 0FFFh | VOUT Under-Voltage Warning detection threshold | 0000h (disabled) |
| 0000h      | VOUT Under-Voltage Warning disabled            | n/a              |

### OT\_FAULT\_LIMIT (4Fh)

The OT\_FAULT\_LIMIT command is a standard PMBus command that allows configuring or reading the threshold for the over-temperature fault detection. Reading and writing to this register should use the coefficients shown in [Table 41](#). Accesses to this command should use the PMBus read or write word protocol. If the measured temperature exceeds this value, an over-temperature fault is triggered and the MOSFET is switched off, OT FAULT flags set, and the SMBA signal asserted. After the measured temperature falls below the value in this register, the MOSFET may be switched back on with the OPERATION command. A single temperature measurement is an average of 16 round-robin cycles; therefore, the minimum temperature fault detection time is 16 ms.

**Table 5. OT\_FAULT\_LIMIT Register**

| Value      | Meaning                                   | Default       |
|------------|---|---------------|
| 0h – 0FFEh | Over-temperature Fault threshold value    | 0960h (150°C) |
| 0FFFh      | Over-temperature Fault detection disabled | n/a           |

**OT\_WARN\_LIMIT (51h)**

The OT\_WARN\_LIMIT command is a standard PMBus command that allows configuring or reading the threshold for the over-temperature warning detection. Reading and writing to this register should use the coefficients shown in [Table 41](#). Accesses to this command should use the PMBus read or write word protocol. If the measured temperature exceeds this value, an over-temperature warning is triggered and the OT\_WARN flags set in the respective registers and the SMBA signal asserted. A single temperature measurement is an average of 16 round-robin cycles; therefore, the minimum temperature warn detection time is 16 ms.

**Table 6. OT\_WARN\_LIMIT Register**

| Value      | Meaning                                  | Default       |
|------------|--|---------------|
| 0h – 0FFEh | Over-Temperature Warn threshold value    | 07D0h (125°C) |
| 0FFFh      | Over-Temperature Warn detection disabled | n/a           |

**VIN\_OV\_WARN\_LIMIT (57h)**

The VIN\_OV\_WARN\_LIMIT command is a standard PMBus command that allows configuring or reading the threshold for the VIN over-voltage warning detection. Reading and writing to this register should use the coefficients shown in [Table 41](#). Accesses to this command should use the PMBus read or write word protocol. If the measured value of VIN falls below the value in this register, VIN OV Warn flags are set in the respective registers and the SMBA signal is asserted.

**Table 7. VIN\_OV\_WARN\_LIMIT Register**

| Value      | Meaning                                      | Default          |
|------------|--|------------------|
| 0h – 0FFEh | VIN Over-Voltage Warning detection threshold | 0FFFh (disabled) |
| 0FFFh      | VIN Over-Voltage Warning disabled            | n/a              |

**VIN\_UV\_WARN\_LIMIT (58h)**

The VIN\_UV\_WARN\_LIMIT command is a standard PMBus command that allows configuring or reading the threshold for the VIN under-voltage warning detection. Reading and writing to this register should use the coefficients shown in [Table 41](#). Accesses to this command should use the PMBus read or write word protocol. If the measured value of VIN falls below the value in this register, VIN UV Warn flags are set in the respective register, and the SMBA signal is asserted.

**Table 8. VIN\_UV\_WARN\_LIMIT Register**

| Value      | Meaning                                       | Default          |
|------------|---|------------------|
| 1h – 0FFFh | VIN Under-Voltage Warning detection threshold | 0000h (disabled) |
| 0000h      | VIN Under-Voltage Warning disabled            | n/a              |

### STATUS\_BYTE (78h)

The STATUS\_BYTE is a standard PMBus command that returns the value of a number of flags indicating the state of the LM5064. Accesses to this command should use the PMBus read byte protocol. To clear bits in this register, the underlying fault should be removed on the system and a CLEAR\_FAULTS command issued.

**Table 9. STATUS\_BYTE Definitions**

| Bit | Name              | Meaning   | Default |
|-----|-------------------|---|---------|
| 7   | BUSY              | Not Supported, always 0   | 0       |
| 6   | OFF               | This bit is asserted if the MOSFET is not switched on for any reason. | 1       |
| 5   | VOUT OV           | Not Supported, always 0   | 0       |
| 4   | IOUT OC           | Not Supported, always 0   | 0       |
| 3   | VIN UV FAULT      | A VIN Under-Voltage Fault has occurred                                | 1       |
| 2   | TEMPERATURE       | A Temperature Fault or Warning has occurred                           | 0       |
| 1   | CML               | A Communication Fault has occurred                                    | 0       |
| 0   | None of the Above | A fault or warning not listed in bits [7:1] has occurred              | 1       |

### STATUS\_WORD (79h)

The STATUS\_WORD command is a standard PMBus command that returns the value of a number of flags indicating the state of the LM5064. Accesses to this command should use the PMBus read word protocol. To clear bits in this register, the underlying fault should be removed and a CLEAR\_FAULTS command issued. The INPUT and VIN UV flags will default to 1 on startup, however, they will be cleared to 0 after the first time the input voltage exceeds the resistor-programmed UVLO threshold.

**Table 10. STATUS\_WORD Definitions**

| Bit | Name              | Meaning   | Default |
|-----|-------------------|---|---------|
| 15  | VOUT              | An output voltage fault or warning has occurred                       | 0       |
| 14  | IOUT/POUT         | Not Supported, always 0   | 0       |
| 13  | INPUT             | An input voltage or current fault has occurred                        | 1       |
| 12  | MFR               | A Manufacturer Specific Fault or Warning has occurred                 | 1       |
| 11  | POWER GOOD        | The Power Good signal has been negated                                | 1       |
| 10  | FANS              | Not Supported, always 0   | 0       |
| 9   | OTHER             | Not Supported, always 0   | 0       |
| 8   | UNKNOWN           | Not Supported, always 0   | 0       |
| 7   | BUSY              | Not Supported, always 0   | 0       |
| 6   | OFF               | This bit is asserted if the MOSFET is not switched on for any reason. | 1       |
| 5   | VOUT OV           | Not Supported, always 0   | 0       |
| 4   | IOUT OC           | Not Supported, always 0   | 0       |
| 3   | VIN UV FAULT      | A VIN Under-Voltage Fault has occurred                                | 1       |
| 2   | TEMPERATURE       | A Temperature Fault or Warning has occurred                           | 0       |
| 1   | CML               | A Communication Fault has occurred                                    | 0       |
| 0   | None of the Above | A fault or warning not listed in bits [7:1] has occurred              | 1       |

### STATUS\_VOUT (7Ah)

The STATUS\_VOUT command is a standard PMBus command that returns the value of the VOUT UV Warn flag. Accesses to this command should use the PMBus read byte protocol. To clear bits in this register, the underlying fault should be cleared and a CLEAR\_FAULTS command issued.

**Table 11. STATUS\_VOUT Definitions**

| Bit | Name                | Meaning                                   | Default |
|-----|---------------------|---|---------|
| 7   | VOUT OV Fault       | Not Supported, always 0                   | 0       |
| 6   | VOUT OV Warn        | Not Supported, always 0                   | 0       |
| 5   | VOUT UV Warn        | A VOUT Under-Voltage Warning has occurred | 0       |
| 4   | VOUT UV Fault       | Not Supported, always 0                   | 0       |
| 3   | VOUT Max            | Not Supported, always 0                   | 0       |
| 2   | TON Max Fault       | Not Supported, always 0                   | 0       |
| 1   | TOFF Max Fault      | Not Supported, always 0                   | 0       |
| 0   | VOUT Tracking Error | Not Supported, always 0                   | 0       |

### STATUS\_INPUT (7Ch)

The STATUS\_INPUT command is a standard PMBus command that returns the value of a number of flags related to input voltage, current, and power. Accesses to this command should use the PMBus read byte protocol. To clear bits in this register, the underlying fault should be cleared and a CLEAR\_FAULTS command issued. The VIN UV Warn flag will default to 1 on startup, however, it will be cleared to 0 after the first time the input voltage increases above the resistor-programmed UVLO threshold.

**Table 12. STATUS\_INPUT Definitions**

| Bit | Name                 | Meaning                                  | Default |
|-----|----------------------|--|---------|
| 7   | VIN OV Fault         | A VIN Over-Voltage Fault has occurred    | 0       |
| 6   | VIN OV Warn          | A VIN Over-Voltage Warning has occurred  | 0       |
| 5   | VIN UV Warn          | A VIN Under-Voltage Warning has occurred | 1       |
| 4   | VIN UV Fault         | A VIN Under-Voltage Fault has occurred   | 0       |
| 3   | Insufficient Voltage | Not Supported, always 0                  | 0       |
| 2   | IIN OC Fault         | An IIN Over-Current Fault has occurred   | 0       |
| 1   | IIN OC Warn          | An IIN Over-Current Warning has occurred | 0       |
| 0   | PIN OP Warn          | A PIN Over-Power Warning has occurred    | 0       |

### STATUS\_TEMPERATURE (7dh)

The STATUS\_TEMPERATURE is a standard PMBus command that returns the value of the of a number of flags related to the temperature telemetry value. Accesses to this command should use the PMBus read byte protocol. To clear bits in this register, the underlying fault should be cleared and a CLEAR\_FAULTS command issued.

**Table 13. STATUS\_TEMPERATURE Definitions**

| Bit | Name            | Meaning                                  | Default |
|-----|-----------------|--|---------|
| 7   | Overtemp Fault  | An Over-Temperature Fault has occurred   | 0       |
| 6   | Overtemp Warn   | An Over-Temperature Warning has occurred | 0       |
| 5   | Undertemp Warn  | Not Supported, always 0                  | 0       |
| 4   | Undertemp Fault | Not Supported, always 0                  | 0       |
| 3   | reserved        | Not Supported, always 0                  | 0       |
| 2   | reserved        | Not Supported, always 0                  | 0       |
| 1   | reserved        | Not Supported, always 0                  | 0       |
| 0   | reserved        | Not Supported, always 0                  | 0       |

### STATUS\_CML (7Eh)

The STATUS\_CML is a standard PMBus command that returns the value of a number of flags related to communication faults. Accesses to this command should use the PMBus read byte protocol. To clear bits in this register, a CLEARFAULTS command should be issued.

**Table 14. STATUS\_CML Definitions**

| Bit | NAME  | Default |
|-----|---|---------|
| 7   | Invalid or unsupported command received         | 0       |
| 6   | Invalid or unsupported data received            | 0       |
| 5   | Packet Error Check failed                       | 0       |
| 4   | Not supported, always 0                         | 0       |
| 3   | Not supported, always 0                         | 0       |
| 2   | Not supported, always 0                         | 0       |
| 1   | Miscellaneous communications fault has occurred | 0       |
| 0   | Not supported, always 0                         | 0       |

### STATUS\_MFR\_SPECIFIC (80h)

The STATUS\_MFR\_SPECIFIC command is a standard PMBus command that contains manufacturer specific status information. Accesses to this command should use the PMBus read byte protocol. To clear bits in this register, the underlying fault should be removed and a CLEARFAULTS command should be issued.

**Table 15. STATUS\_MFR\_SPECIFIC Definitions**

| Bit | Meaning                   | Default |
|-----|---------------------------|---------|
| 7   | Circuit breaker fault     | 0       |
| 6   | Ext. MOSFET shorted fault | 0       |
| 5   | Not Supported, Always 0   | 0       |
| 4   | Defaults loaded           | 1       |
| 3   | Not supported: Always 0   | 0       |
| 2   | Not supported: Always 0   | 0       |
| 1   | Not supported: Always 0   | 0       |
| 0   | Not supported: Always 0   | 0       |

### READ\_VIN (88h)

The READ\_VIN command is a standard PMBus command that returns the 12-bit measured value of the input voltage. Reading this register should use the coefficients shown in [Table 41](#). Accesses to this command should use the PMBus read word protocol. This value is also used internally for the VIN Over and Under-Voltage Warning detection.

**Table 16. READ\_VIN Register**

| Value      | Meaning                | Default |
|------------|------------------------|---------|
| 0h – 0FFFh | Measured value for VIN | 0000h   |

### READ\_VOUT (8Bh)

The READ\_VOUT command is a standard PMBus command that returns the 12-bit measured value of the output voltage. Reading this register should use the coefficients shown in [Table 41](#). Accesses to this command should use the PMBus read word protocol. This value is also used internally for the VOUT Under-Voltage Warning detection.

**Table 17. READ\_VOUT Register**

| Value      | Meaning                 | Default |
|------------|-------------------------|---------|
| 0h – 0FFFh | Measured value for VOUT | 0000h   |

### READ\_TEMPERATURE\_1 (8Dh)

The READ\_TEMPERATURE\_1 command is a standard PMBus command that returns the signed value of the temperature measured by the external temperature sense diode. Reading this register should use the coefficients shown in [Table 41](#). Accesses to this command should use the PMBus read word protocol. This value is also used internally for the Over-Temperature Fault and Warning detection. This data has a range of -256°C to + 255°C after the coefficients are applied.

**Table 18. READ\_TEMPERATURE\_1 Register**

| Value      | Meaning                        | Default |
|------------|--------------------------------|---------|
| 0h – 0FFFh | Measured value for TEMPERATURE | 0000h   |

### MFR\_ID (99h)

The MFR\_ID command is a standard PMBus command that returns the identification of the manufacturer. To read the MFR\_ID, use the PMBus block read protocol.

**Table 19. MFR\_ID Register**

| Byte | Name            | Value   |
|------|-----------------|---------|
| 0    | Number of bytes | 03h     |
| 1    | MFR ID-1        | 4Eh 'N' |
| 2    | MFR ID-2        | 53h 'S' |
| 3    | MFR ID-3        | 43h 'C' |

### MFR\_MODEL (9Ah)

The MFR\_MODEL command is a standard PMBus command that returns the part number of the chip. To read the MFR\_MODEL, use the PMBus block read protocol.

**Table 20. MFR\_MODEL Register**

| Byte | Name            | Value   |
|------|-----------------|---------|
| 0    | Number of bytes | 08h     |
| 1    | MFR ID-1        | 4Ch 'L' |
| 2    | MFR ID-2        | 4Dh 'M' |
| 3    | MFR ID-3        | 35h '5' |
| 4    | MFR ID-4        | 30h '0' |
| 5    | MFR ID-5        | 36h '6' |
| 6    | MFR ID-6        | 36h '4' |
| 7    | MFR ID-7        | 00h     |
| 8    | MFR ID-8        | 00h     |

**MFR\_REVISION (9Bh)**

The MFR\_REVISION command is a standard PMBus command that returns the revision level of the part. To read the MFR\_REVISION, use the PMBus block read protocol.

**Table 21. MFR\_REVISION Register**

| Byte | Name            | Value   |
|------|-----------------|---------|
| 0    | Number of bytes | 02h     |
| 1    | MFR ID-1        | 41h 'A' |
| 2    | MFR ID-2        | 41h 'A' |

## MANUFACTURER SPECIFIC PMBUS™ COMMANDS

### MFR\_SPECIFIC\_00: READ\_VAUX (D0h)

The READ\_VAUX command will report the 12-bit ADC measured auxiliary voltage. Voltages greater than or equal to 2.97V to VEE will be reported at plus full scale (0FFFh). Voltages less than or equal to 0V referenced to VEE will be reported as 0 (0000h). To read data from the READ\_VAUX command, use the PMBus Read Word protocol.

**Table 22. READ\_VAUX Register**

| Value      | Meaning                       | Default |
|------------|-------------------------------|---------|
| 0h – 0FFFh | Measured value for VAUX input | 0000h   |

### MFR\_SPECIFIC\_01: MFR\_READ\_IIN (D1h)

The MFR\_READ\_IIN command will report the 12-bit ADC measured current sense voltage. To read data from the MFR\_READ\_IIN command, use the PMBus Read Word protocol. Reading this register should use the coefficients shown in [Table 41](#). Please see the section on coefficient calculations to calculate the values to use.

**Table 23. MFR\_READ\_IIN Register**

| Value      | Meaning  | Default |
|------------|--|---------|
| 0h – 0FFFh | Measured value for input current sense voltage | 0000h   |

### MFR\_SPECIFIC\_02: MFR\_READ\_PIN (D2h)

The MFR\_READ\_PIN command will report the upper 12 bits of the VIN x IIN product as measured by the 12-bit ADC. To read data from the MFR\_READ\_PIN command, use the PMBus Read Word protocol. Reading this register should use the coefficients shown in [Table 41](#). Please see the section on coefficient calculations to calculate the values to use.

**Table 24. MFR\_READ\_PIN Register**

| Value      | Meaning                                 | Default |
|------------|---|---------|
| 0h – 0FFFh | Value for input current x input voltage | 0000h   |

### MFR\_SPECIFIC\_03: MFR\_IN\_OC\_WARN\_LIMIT (D3h)

The MFR\_IIN\_OC\_WARN\_LIMIT PMBus command sets the input over-current warning threshold. In the event that the input current rises above the value set in this register, the IIN over-current flags are set in the respective registers and the SMBA is asserted. To access the MFR\_IIN\_OC\_WARN\_LIMIT register, use the PMBus Read/Write Word protocol. Reading/writing to this register should use the coefficients shown in [Table 41](#).

**Table 25. MFR\_IIN\_OC\_WARN\_LIMIT Register**

| Value      | Meaning                                 | Default |
|------------|---|---------|
| 0h – 0FFEh | Value for input over-current warn limit | 0FFFh   |
| 0FFFh      | Input over-current warning disabled     | n/a     |

#### **MFR\_SPECIFIC\_04: MFR\_PIN\_OP\_WARN\_LIMIT (D4h)**

The MFR\_PIN\_OP\_WARN\_LIMIT PMBus command sets the input over-power warning threshold. In the event that the input power rises above the value set in this register, the PIN over-power flags are set in the respective registers and the SMBA is asserted. To access the MFR\_PIN\_OP\_WARN\_LIMIT register, use the PMBus Read/Write Word protocol. Reading/writing to this register should use the coefficients shown in [Table 41](#).

**Table 26. MFR\_PIN\_OPWARN\_LIMIT Register**

| Value      | Meaning                               | Default |
|------------|---------------------------------------|---------|
| 0h – OFFEh | Value for input over-power warn limit | 0FFFh   |
| 0FFFh      | Input over-power warning disabled     | n/a     |

#### **MFR\_SPECIFIC\_05: READ\_PIN\_PEAK (D5h)**

The READ\_PIN\_PEAK command will report the maximum input power measured since a Power On reset or the last CLEAR\_PIN\_PEAK command. To access the READ\_PIN\_PEAK command, use the PMBus Read Word protocol. Use the coefficients shown in [Table 41](#).

**Table 27. READ\_PIN\_PEAK Register**

| Value      | Meaning   | Default |
|------------|---|---------|
| 0h – OFFEh | Maximum Value for input current x input voltage since reset or last clear | 0h      |

#### **MFR\_SPECIFIC\_06: CLEAR\_PIN\_PEAK (D6h)**

The CLEAR\_PIN\_PEAK command will clear the PIN PEAK register. This command uses the PMBus Send Byte protocol.

#### **MFR\_SPECIFIC\_07: GATE\_MASK (D7h)**

The GATE\_MASK register allows the hardware to prevent fault conditions from switching off the MOSFET. When the bit is high, the corresponding FAULT has no control over the MOSFET gate. All status registers will still be updated (STATUS, DIAGNOSTIC) and an SMBA will still be asserted. This register is accessed with the PMBus Read / Write Byte protocol.

The IIN/PFET Fault refers to the input current fault and the MOSFET power dissipation fault. There is no input power fault detection; only input power warning detection.

**WARNING**

**Inhibiting the MOSFET switch off in response to over-current or circuit breaker fault conditions will likely result in the destruction of the MOSFET! This functionality should be used with great care and supervision!**

**Table 28. MFR\_SPECIFIC\_07 GATE MASK Definitions**

| Bit | NAME                  | Default |
|-----|-----------------------|---------|
| 7   | Not used, always 0    | 0       |
| 6   | Not used, always 0    | 0       |
| 5   | VIN UV FAULT          | 0       |
| 4   | VIN OV FAULT          | 0       |
| 3   | IIN/PFET FAULT        | 0       |
| 2   | OVERTEMP FAULT        | 0       |
| 1   | Not used, always 0    | 0       |
| 0   | CIRCUIT BREAKER FAULT | 0       |

### MFR\_SPECIFIC\_08: ALERT\_MASK (D8h)

The ALERT\_MASK command is used to mask the SMB<sub>A</sub> when a specific fault or warning has occurred. Each bit corresponds to one of the 14 different analog and digital faults or warnings that would normally result in an SMB<sub>A</sub> being asserted. When the corresponding bit is high, that condition will not cause the SMB<sub>A</sub> to be asserted. If that condition occurs, the registers where that condition is captured will still be updated (STATUS registers, DIAGNOSTIC\_WORD) and the external MOSFET gate control will still be active (VIN\_OV\_FAULT, VIN\_UV\_FAULT, IIN/PFET\_FAULT, CB\_FAULT, OT\_FAULT). This register is accessed with the PMBus Read / Write Word protocol. The VIN UNDERVOLTAGE FAULT flag will default to 1 on startup, however, it will be cleared to 0 after the first time the input voltage increases above the resistor-programmed UVLO threshold.

**Table 29. ALERT\_MASK Definitions**

| BIT | NAME                             | DEFAULT |
|-----|----------------------------------|---------|
| 15  | VOUT UNDERVOLTAGE WARN           | 0       |
| 14  | IIN LIMIT WARN                   | 0       |
| 13  | VIN UNDERVOLTAGE WARN            | 0       |
| 12  | VIN OVERVOLTAGE WARN             | 0       |
| 11  | POWER GOOD                       | 1       |
| 10  | OVERTEMP WARN                    | 0       |
| 9   | Not Used                         | 0       |
| 8   | OVERPOWER LIMIT WARN             | 0       |
| 7   | Not Used                         | 0       |
| 6   | EXT_MOSFET_SHORTED               | 0       |
| 5   | VIN UNDERVOLTAGE FAULT           | 1       |
| 4   | VIN OVERVOLTAGE FAULT            | 0       |
| 3   | IIN/PFET FAULT                   | 0       |
| 2   | OVERTEMPERATURE FAULT            | 0       |
| 1   | CML FAULT (Communications Fault) | 0       |
| 0   | CIRCUIT BREAKER FAULT            | 0       |

### MFR\_SPECIFIC\_09: DEVICE\_SETUP (D9h)

The DEVICE\_SETUP command may be used to override pin settings to define operation of the LM5064 under host control. This command is accessed with the PMBus read / write byte protocol.

**Table 30. DEVICE\_SETUP Byte Format**

| Bit | Name                        | Meaning                                  |
|-----|-----------------------------|--|
| 7:5 | Retry setting               | 111 = Unlimited retries                  |
|     |                             | 110 = Retry 16 times                     |
|     |                             | 101 = Retry 8 times                      |
|     |                             | 100 = Retry 4 times                      |
|     |                             | 011 = Retry 2 times                      |
|     |                             | 010 = Retry 1 time                       |
|     |                             | 001 = No retries                         |
|     |                             | 000 = Pin configured retries             |
| 4   | Current limit setting       | 0 = High setting (50 mV)                 |
|     |                             | 1 = Low setting (26 mV)                  |
| 3   | CB/CL Ratio                 | 0 = Low setting (1.8/1.9x for 26/50 mV)  |
|     |                             | 1 = High setting (3.6/3.7x for 26/50 mV) |
| 2   | Current Limit Configuration | 0 = Use pin settings                     |
|     |                             | 1 = Use SMBus settings                   |
| 1   | Unused                      |  |

**Table 30. DEVICE\_SETUP Byte Format (continued)**

| Bit | Name   | Meaning |
|-----|--------|---------|
| 0   | Unused |         |

In order to configure the Current Limit Setting via this register, it is necessary to set the Current Limit Configuration bit (2) to 1 to enable the register to control the current limit function and the Current Limit Setting bit (4) to select the desired setting. If the Current Limit Configuration bit is not set, the pin setting will be used. The Circuit Breaker to Current Limit ratio value is set by the CB / CL Ratio bit (3). Note that if the Current Limit Configuration is changed, the samples for the telemetry averaging function will not be reset. It is recommended to allow a full averaging update period with the new Current Limit Configuration before processing the averaged data.

Note that the Current Limit Configuration affects the coefficients used for the Current and Power measurements and warning registers.

#### **MFR\_SPECIFIC\_10: BLOCK\_READ (DAh)**

The BLOCK\_READ command concatenates the DIAGNOSTIC\_WORD with input and output telemetry information (IIN, VOUT, VIN, PIN) as well as READ\_TEMPERATURE\_1 to capture all of the operating information of the LM5064 in a single SMBus transaction. The block is 12 bytes long with telemetry information being sent out in the same manner as if an individual READ\_XXX command had been issued (shown below). The contents of the block read register are updated every clock cycle (85ns) as long as the SMBus interface is idle. BLOCK\_READ also ensures that the VIN, VOUT, IIN and PIN measurements are all time-aligned. If separate commands are used, individual samples may not be time-aligned, because of the delay necessary for the communication protocol.

The Block Read command is read via the PMBus block read protocol.

**Table 31. BLOCK\_READ Register Format**

|                        |          |
|------------------------|----------|
| Byte Count (always 12) | (1 byte) |
| DIAGNOSTIC_WORD        | (1 Word) |
| IIN_BLOCK              | (1 Word) |
| VOUT_BLOCK             | (1 Word) |
| VIN_BLOCK              | (1 Word) |
| PIN_BLOCK              | (1 Word) |
| TEMP_BLOCK             | (1 Word) |

#### **MFR\_SPECIFIC\_11: SAMPLES\_FOR\_AVG (DBh)**

The SAMPLES\_FOR\_AVG command is a manufacturer specific command for setting the number of samples used in computing the average values for IIN, VIN, VOUT, PIN. The decimal equivalent of the AVGN nibble is the power of 2 samples, (e.g. AVGN=12 equates to N=4096 samples used in computing the average). The LM5064 supports average numbers of 1, 2, 4, 8, 16, 32, 64, 128, 256, 512, 1024, 2048, 4096. The SAMPLES\_FOR\_AVG number applies to average values of IIN, VIN, VOUT, PIN simultaneously. The LM5064 uses simple averaging. This is accomplished by summing consecutive results up to the number programmed, then dividing by the number of samples. Averaging is calculated according to the following sequence:

$$Y = (X_{(N)} + X_{(N-1)} + \dots + X_{(0)}) / N \quad (33)$$

When the averaging has reached the end of a sequence (for example, 4096 samples are averaged), then a whole new sequence begins that will require the same number of samples (in this example, 4096) to be taken before the new average is ready.

**Table 32. SAMPLES\_FOR\_AVG Register**

| AVGN | $N = 2^{AVGN}$ | Averaging/Register Update Period (ms) |
|------|----------------|---------------------------------------|
| 0000 | 1              | 1                                     |
| 0001 | 2              | 2                                     |
| 0010 | 4              | 4                                     |

**Table 32. SAMPLES\_FOR\_AVG Register (continued)**

| AVGN | $N = 2^{AVGN}$ | Averaging/Register Update Period (ms) |
|------|----------------|---------------------------------------|
| 0011 | 8              | 8                                     |
| 0100 | 16             | 16                                    |
| 0101 | 32             | 32                                    |
| 0110 | 64             | 64                                    |
| 0111 | 128            | 128                                   |
| 1000 | 256            | 256                                   |
| 1001 | 512            | 512                                   |
| 1010 | 1024           | 1024                                  |
| 1011 | 2048           | 2048                                  |
| 1100 | 4096           | 4096                                  |

Note that a change in the SAMPLES\_FOR\_AVG register will not be reflected in the average telemetry measurements until the present averaging interval has completed. The default setting for AVGN is 0000, therefore, the average telemetry will mirror the instantaneous telemetry until a value higher than zero is programmed.

The SAMPLES\_FOR\_AVG register is accessed via the PMBus read / write byte protocol.

**Table 33. SAMPLES\_FOR\_AVG Register**

| Value    | Meaning   | Default |
|----------|---|---------|
| 0h – 0Ch | Exponent (AVGN) for number of samples to average over | 00h     |

#### MFR\_SPECIFIC\_12: READ\_AVG\_VIN (DCh)

The READ\_AVG\_VIN command will report the 12-bit ADC measured input average voltage. If the data is not ready, the returned value will be the previous averaged data. However, if there is no previously averaged data, the default value (0000h) will be returned. This data is read with the PMBus Read Word protocol. This register should use the coefficients shown in [Table 41](#).

**Table 34. READ\_AVG\_VIN Register**

| Value      | Meaning                                      | Default |
|------------|--|---------|
| 0h – 0FFFh | Average of measured values for input voltage | 0000h   |

#### MFR\_SPECIFIC\_13: READ\_AVG\_VOUT (DDh)

The READ\_AVG\_VOUT command will report the 12-bit ADC measured OUT pin average voltage. The returned value will be the default value (0000h) or previous data when the average data is not ready. This data is read with the PMBus Read Word protocol. This register should use the coefficients shown in [Table 41](#).

**Table 35. READ\_AVG\_VOUT Register**

| Value      | Meaning                                       | Default |
|------------|---|---------|
| 0h – 0FFFh | Average of measured values for output voltage | 0000h   |

#### MFR\_SPECIFIC\_14: READ\_AVG\_IIN (DEh)

The READ\_AVG\_IIN command will report the 12-bit ADC measured VAUXH average voltage. The returned value will be the default value (0000h) or previous data when the average data is not ready. This data is read with the PMBus Read Word protocol. This register should use the coefficients shown in [Table 41](#).

**Table 36. READ\_AVG\_IIN Register**

| Value      | Meaning  | Default |
|------------|--|---------|
| 0h – 0FFFh | Average of measured values for current sense voltage | 0000h   |

**MFR\_SPECIFIC\_15: READ\_AVG\_PIN**

The READ\_AVG\_PIN command will report the upper 12-bits of the average  $V_{IN} \times I_{IN}$  product as measured by the 12-bit ADC. You will read the default value (0000h) or previous data when the average data is not ready. This data is read with the PMBus Read Word protocol. This register should use the coefficients shown in Table 41.

**Table 37. READ\_AVG\_PIN Register**

| Value      | Meaning   | Default |
|------------|---|---------|
| 0h – 0FFFh | Average of measured value for input voltage x input current sense voltage | 0000h   |

**MFR\_SPECIFIC\_16: BLACK\_BOX\_READ (E0h)**

The BLACK BOX READ command retrieves the BLOCK READ data which was latched in at the first assertion of SMBA by the LM5064. It is re-armed with the CLEAR\_FAULTS command. It is the same format as the BLOCK\_READ registers, the only difference being that its contents are updated with the SMBA edge rather than the internal clock edge. This command is read with the PMBus Block Read protocol.

**MFR\_SPECIFIC\_17: READ\_DIAGNOSTIC\_WORD (E1h)**

The READ\_DIAGNOSTIC\_WORD PMBus command will report all of the LM5064 faults and warnings in a single read operation. The standard response to the assertion of the SMBA signal of issuing multiple read requests to various status registers can be replaced by a single word read to the DIAGNOSTIC\_WORD register. The READ\_DIAGNOSTIC\_WORD command should be read with the PMBus Read Word protocol. The READ\_DIAGNOSTIC\_WORD is also returned in the BLOCK\_READ, BLACK\_BOX\_READ, and AVG\_BLOCK\_READ operations.

**Table 38. DIAGNOSTIC\_WORD Format**

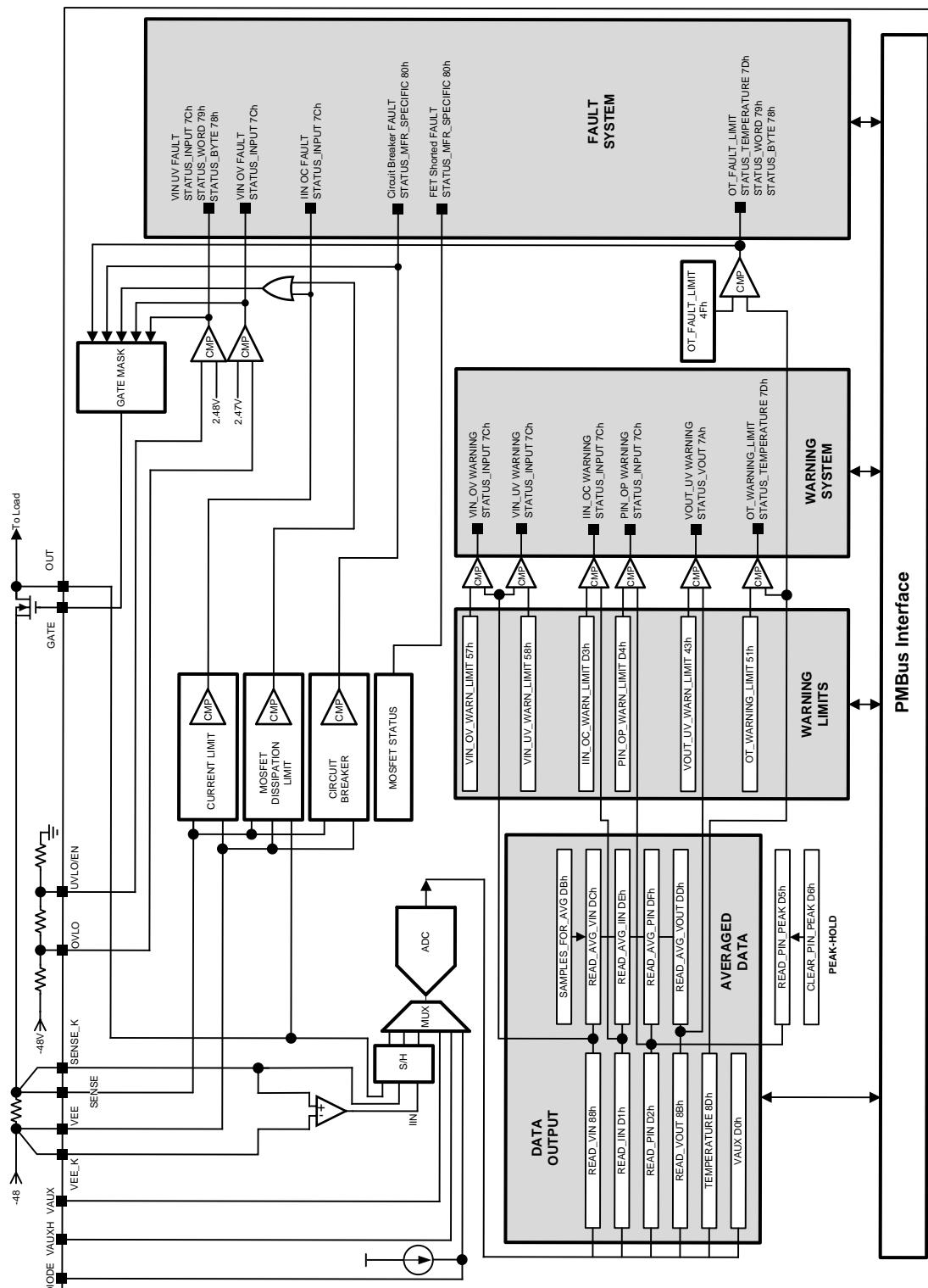
| Bit | Meaning                     | Default |
|-----|-----------------------------|---------|
| 15  | $V_{OUT}$ UNDERVOLTAGE WARN | 0       |
| 14  | OC/OP WARN                  | 0       |
| 13  | $V_{IN}$ UNDERVOLTAGE WARN  | 0       |
| 12  | $V_{IN}$ OVERVOLTAGE WARN   | 0       |
| 11  | POWER GOOD                  | 1       |
| 10  | OVER TEMPERATURE WARN       | 0       |
| 9   | TIMER LATCHED OFF           | 0       |
| 8   | EXT MOSFET SHORTED          | 0       |
| 7   | CONFIG PRESET               | 1       |
| 6   | DEVICE OFF                  | 1       |
| 5   | $V_{IN}$ UNDERVOLTAGE FAULT | 1       |
| 4   | $V_{IN}$ OVERVOLTAGE FAULT  | 0       |
| 3   | IIN OC/PFET OP FAULT        | 0       |
| 2   | OVER TEMPERATURE FAULT      | 0       |
| 1   | CML FAULT                   | 0       |
| 0   | CIRCUIT BREAKER FAULT       | 0       |

**MFR\_SPECIFIC\_18: AVG\_BLOCK\_READ (E2h)**

The AVG\_BLOCK\_READ command concatenates the DIAGNOSTIC\_WORD with input and output average telemetry information (IIN, VOUT, VIN, PIN) as well as temperature to capture all of the operating information of the part in a single PMBus transaction. The block is 12 bytes long with telemetry information being sent out in the same manner as if an individual READ\_AVG\_XXX command had been issued (shown below). AVG\_BLOCK\_READ also ensures that the VIN, VOUT, and IIN measurements are all time-aligned whereas there is a chance they may not be if read with individual PMBus commands. To read data from the AVG\_BLOCK\_READ command, use the SMBus Block Read protocol.

**Table 39. AVG\_BLOCK\_READ Register Format**

|                        |          |
|------------------------|----------|
| Byte Count (always 12) | (1 byte) |
| DIAGNOSTIC_WORD        | (1 word) |
| AVG_IIN                | (1 word) |
| AVG_VOUT               | (1 word) |
| AVG_VIN                | (1 word) |
| AVG_PIN                | (1 word) |
| TEMPERATURE            | (1 word) |


**Figure 19. Command/Register and Alert Flow Diagram**

## READING AND WRITING TELEMETRY DATA AND WARNING THRESHOLDS

All measured telemetry data and user programmed warning thresholds are communicated in 12-bit two's compliment binary numbers read/written in 2 byte increments conforming to the Direct format as described in section 8.3.3 of the PMBus Power System Management Protocol Specification 1.1 (Part II). The organization of the bits in the telemetry or warning word is shown in [Table 40](#), where Bit\_11 is the most significant bit (MSB) and Bit\_0 is the least significant bit (LSB). The decimal equivalent of all warning and telemetry words are constrained to be within the range of 0 to 4095, with the exception of temperature. The decimal equivalent value of the temperature word ranges from 0 to 65535.

**Table 40. Telemetry and Warning Word Format**

| Byte | B7    | B6    | B5    | B4    | B3     | B2     | B1    | B0    |
|------|-------|-------|-------|-------|--------|--------|-------|-------|
| 1    | Bit_7 | Bit_6 | Bit_5 | Bit_4 | Bit_3  | Bit_2  | Bit_1 | Bit_0 |
| 2    | 0     | 0     | 0     | 0     | Bit_11 | Bit_10 | Bit_9 | Bit_8 |

Conversion from direct format to real-world dimensions of current, voltage, power, and temperature is accomplished by determining appropriate coefficients as described in section 7.2.1 of the PMBus Power System Management Protocol Specification 1.1 (Part II). According to this specification, the host system converts the values received into a reading of volts, amperes, watts, or other units using the following relationship:

$$X = \frac{1}{m} (Y \times 10^R - b) \quad (34)$$

Where:

**X:** the calculated "real-world" value (volts, amps, watt, etc.)

**m:** the slope coefficient

**Y:** a two byte two's complement integer received from device

**b:** the offset, a two byte, two's complement integer

**R:** the exponent, a one byte two's complement integer

R is only necessary in systems where m is required to be an integer (for example, where m may be stored in a register in an integrated circuit). In those cases, R only needs to be large enough to yield the desired accuracy.

**Table 41. Telemetry and Warning Conversion Coefficients**

| Commands   | Condition | Format | Number of Data Bytes | m     | b     | R  | Units |
|--|-----------|--------|----------------------|-------|-------|----|-------|
| READ_VIN, READ_AVG_VIN<br>VIN_OV_WARN_LIMIT<br>VIN_UV_WARN_LIMIT                 |           | DIRECT | 2                    | 4611  | -642  | -2 | V     |
| READ_VOUT, READ_AVG_VOUT<br>VOUT_UV_WARN_LIMIT                                   |           | DIRECT | 2                    | 4621  | 423   | -2 | V     |
| READ_VAUX  |           | DIRECT | 2                    | 13808 | 0     | -1 | V     |
| <sup>(1)</sup> READ_IIN, READ_AVG_IIN<br>MFR_IIN_OC_WARN_LIMIT                   | CL = VDD  | DIRECT | 2                    | 10742 | 1552  | -2 | A     |
| <sup>(1)</sup> READ_IN, READ_AVG_IN<br>MFR_IIN_OC_WARN_LIMIT                     | CL = VEE  | DIRECT | 2                    | 5456  | 2118  | -2 | A     |
| <sup>(1)</sup> READ_PIN, READ_AVG_PIN,<br>READ_PIN_PEAK<br>MFR_PIN_OP_WARN_LIMIT | CL = VDD  | DIRECT | 2                    | 1204  | 8524  | -3 | W     |
| <sup>(1)</sup> READ_PIN, READ_AVG_PIN,<br>READ_PIN_PEAK<br>MFR_PIN_OP_WARN_LIMIT | CL = VEE  | DIRECT | 2                    | 612   | 11202 | -3 | W     |
| READ_TEMPERATURE_1<br>OT_WARN_LIMIT<br>OT_FAULT_LIMIT                            |           | DIRECT | 2                    | 16000 | 0     | -3 | °C    |

(1) The coefficients relating to current/power measurements and warning thresholds shown are normalized to a sense resistor ( $R_S$ ) value of 1 mΩ. In general, the current/power coefficients can be calculated using the relationships shown in [Table 42](#).

**Table 42. Current and Power Telemetry and Warning Conversion Coefficients ( $R_S$  in  $m\Omega$ )**

| Commands   | Condition | Format | Number of Data Bytes | m                  | b     | R  | Units |
|--|-----------|--------|----------------------|--------------------|-------|----|-------|
| <sup>(1)</sup> READ_IIN, READ_AVG_IIN<br>MFR_IIN_OC_WARN_LIMIT                   | CL = VDD  | DIRECT | 2                    | $10742 \times R_S$ | 1552  | -2 | A     |
| <sup>(1)</sup> READ_IIN, READ_AVG_IIN<br>MFR_IIN_OC_WARN_LIMIT                   | CL = VEE  | DIRECT | 2                    | $5456 \times R_S$  | 2118  | -2 | A     |
| <sup>(1)</sup> READ_PIN, READ_AVG_PIN,<br>READ_PIN_PEAK<br>MFR_PIN_OP_WARN_LIMIT | CL = VDD  | DIRECT | 2                    | $1204 \times R_S$  | 8524  | -3 | W     |
| <sup>(1)</sup> READ_PIN, READ_AVG_PIN,<br>READ_PIN_PEAK<br>MFR_PIN_OP_WARN_LIMIT | CL = VEE  | DIRECT | 2                    | $612 \times R_S$   | 11202 | -3 | W     |

(1) The coefficients relating to current/power measurements and warning thresholds shown in [Table 41](#) are normalized to a sense resistor ( $R_S$ ) value of  $1 m\Omega$ . In general, the current/power coefficients can be calculated using the relationships shown.

Care must be taken to adjust the exponent coefficient, R, such that the value of m remains within the range of -32768 to +32767. For example, if a  $5 m\Omega$  sense resistor is used, the correct coefficients for the READ\_IIN command with CL = VDD would be m = 5371, b = 155, R = -1.

## DETERMINING TELEMETRY COEFFICIENTS EMPIRICALLY WITH LINEAR FIT

The coefficients for telemetry measurements and warning thresholds presented in [Table 41](#) are adequate for the majority of applications. Current and power coefficients must be calculated per application as they are dependent on the value of the sense resistor,  $R_S$ , used. [Table 42](#) provides the equations necessary for calculating the current and power coefficients for the general case. The small signal nature of the current measurement make it and the power measurement more susceptible to PCB parasitics than other telemetry channels. This may cause slight variations in the optimum coefficients ( $m$ ,  $b$ ,  $R$ ) for converting from Direct format digital values to real-world values (for example, Amps and Watts). The optimum coefficients can be determined empirically for a specific application and PCB layout using two or more measurements of the telemetry channel of interest. The current coefficients can be determined using the following method:

1. While the LM5064 is in normal operation measure the voltage across the sense resistor using kelvin test points and a high accuracy DVM while controlling the load current. Record the integer value returned by the READ\_AVG\_IIN command (with the SAMPLES\_FOR\_AVG set to a value greater than 0) for two or more voltages across the sense resistor. For best results, the individual READ\_AVG\_IIN measurements should span nearly the full scale range of the current (For example, voltage across  $R_S$  of 5 mV and 20 mV).
2. Convert the measured voltages to currents by dividing them by the value of  $R_S$ . For best accuracy the value of  $R_S$  should be measured. [Table 43](#) assumes a sense resistor value of 5mΩ.

**Table 43. Measurements for linear fit determination of current coefficients:**

| Measured voltage across $R_S$ (V) | Measured Current (A) | READ_AVG_IIN (integer value) |
|-----------------------------------|----------------------|------------------------------|
| 0.005                             | 1                    | 568                          |
| 0.01                              | 2                    | 1108                         |
| 0.02                              | 4                    | 2185                         |

1. Using the spreadsheet or math program of your choice determine the slope and the y-intercept of the data returned by the READ\_AVG\_IIN command versus the measured current. For the data shown in [Table 42](#):
  - READ\_AVG\_IN value = slope x (Measured Current) + (y-intercept)
  - slope = 538.9
  - y-intercept = 29.5
2. To determine the 'm' coefficient, simply shift the decimal point of the calculated slope to arrive at an integer with a suitable number of significant digits for accuracy (typically 4) while staying with the range of -32768 to +32767. This shift in the decimal point equates to the 'R' coefficient. For the slope value shown above, the decimal point would be shifted to the right once hence  $R = -1$ .
3. Once the 'R' coefficient has been determined, the 'b' coefficient is found by multiplying the y-intercept by  $10^R$ . In this case the value of  $b = 295$ .
  - Calculated Current Coefficients:
  - $m = 5389$
  - $b = 295$
  - $R = -1$
$$X = \frac{1}{m} (Y \times 10^R - b) \quad (35)$$

Where:

**X:** the calculated "real-world" value (volts, amps, watts, temperature)

**m:** the slope coefficient, is the two byte, two's complement integer

**Y:** a two byte two's complement integer received from device

**b:** the offset, a two byte, two's complement integer

**R:** the exponent, a one byte two's complement integer

The above procedure can be repeated to determine the coefficients of any telemetry channel simply by substituting measured current for some other parameter (for example, power, voltage, etc.).

## WRITING TELEMETRY DATA

There are several locations that will require writing data if their optional usage is desired. Use the same coefficients previously calculated for your application, and apply them using this method as prescribed by the PMBus revision section 7.2.2 "Sending a Value"

$$Y = (mX + b) \times 10^R \quad (36)$$

Where:

**X:** the calculated "real-world" value (volts, amps, watts, temperature)

**m:** the slope coefficient, is the two byte, two's complement integer

**Y:** a two byte two's complement integer received from device

**b:** the offset, a two byte, two's complement integer

**R:** the exponent, a one byte two's complement integer

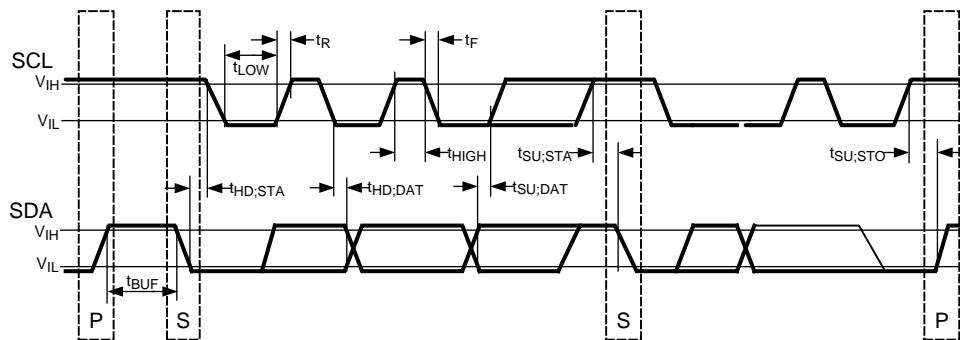
## PMBUS™ ADDRESS LINES (ADR0, ADR1, ADR2)

The three address lines are to be set high (connect to VDD), low (connect to VEE), or open to select one of 27 addresses for communicating with the LM5064. [Table 44](#) depicts 7-bit addresses (eighth bit is read/write bit):

**Table 44. Device Addressing**

| ADR2 | ADR1 | ADR0 | Decoded Address |
|------|------|------|-----------------|
| Z    | Z    | Z    | 40h             |
| Z    | Z    | 0    | 41h             |
| Z    | Z    | 1    | 42h             |
| Z    | 0    | Z    | 43h             |
| Z    | 0    | 0    | 44h             |
| Z    | 0    | 1    | 45h             |
| Z    | 1    | Z    | 46h             |
| Z    | 1    | 0    | 47h             |
| Z    | 1    | 1    | 10h             |
| 0    | Z    | Z    | 11h             |
| 0    | Z    | 0    | 12h             |
| 0    | Z    | 1    | 13h             |
| 0    | 0    | Z    | 14h             |
| 0    | 0    | 0    | 15h             |
| 0    | 0    | 1    | 16h             |
| 0    | 1    | Z    | 17h             |
| 0    | 1    | 0    | 50h             |
| 0    | 1    | 1    | 51h             |
| 1    | Z    | Z    | 52h             |
| 1    | Z    | 0    | 53h             |
| 1    | Z    | 1    | 54h             |
| 1    | 0    | Z    | 55h             |
| 1    | 0    | 0    | 56h             |
| 1    | 0    | 1    | 57h             |
| 1    | 1    | Z    | 58h             |
| 1    | 1    | 0    | 59h             |
| 1    | 1    | 1    | 5Ah             |

## SMBUS COMMUNICATIONS TIMING REQUIREMENTS



**Figure 20. SMBus Timing Diagram**

**Table 45. SMBus Timing Definition**

| Symbol         | Parameter  | Limits |     | Units | Comments |
|----------------|--|--------|-----|-------|----------|
|                |  | Min    | Max |       |          |
| $F_{SMB}$      | SMBus Operating Frequency  | 10     | 400 | kHz   |          |
| $T_{BUF}$      | Bus free time between Stop and Start Condition   | 1.3    |     | μs    |          |
| $T_{HD:STA}$   | Hold time after (Repeated) Start Condition. After this period, the first clock is generated. | 0.6    |     | μs    |          |
| $T_{SU:STA}$   | Repeated Start Condition setup time  | 0.6    |     | μs    |          |
| $T_{SU:STO}$   | Stop Condition setup time  | 0.6    |     | μs    |          |
| $T_{HD:DAT}$   | Data hold time   | 85     |     | ns    |          |
| $T_{SU:DAT}$   | Data setup time  | 100    |     | ns    |          |
| $T_{TIMEOUT}$  | Clock low time-out   | 25     | 35  | ms    | (1)      |
| $T_{LOW}$      | Clock low period   | 1.5    |     | μs    |          |
| $T_{HIGH}$     | Clock high period  | 0.6    |     | μs    | (2)      |
| $T_{LOW:SEXT}$ | Cumulative clock low extend time (slave device)  |        | 25  | ms    | (3)      |
| $T_{LOW:MEXT}$ | Cumulative low extend time (master device)   |        | 10  | ms    | (4)      |
| $T_F$          | Clock or Data Fall Time  | 20     | 300 | ns    | (5)      |
| $T_R$          | Clock or Data Rise Time  | 20     | 300 | ns    | (5)      |

- (1) Devices participating in a transfer will timeout when any clock low exceeds the value of  $T_{TIMEOUT,MIN}$  of 25 ms. Devices that have detected a timeout condition must reset the communication no later than  $T_{TIMEOUT,MAX}$  of 35 ms. The maximum value must be adhered to by both a master and a slave as it incorporates the cumulative stretch limit for both a master (10ms) and a slave (25ms).
- (2)  $T_{HIGH\ MAX}$  provides a simple method for devices to detect bus idle conditions.
- (3)  $T_{LOW:SEXT}$  is the cumulative time a slave device is allowed to extend the clock cycles in one message from the initial start to the stop. If a slave exceeds this time, it is expected to release both its clock and data lines and reset itself.
- (4)  $T_{LOW:MEXT}$  is the cumulative time a master device is allowed to extend its clock cycles within each byte of a message as defined from start-to-ack, ack-to-ack, or ack-to-stop.
- (5) Rise and fall time is defined as follows:
  - $T_R = (V_{ILMAX} - 0.15)$  to  $(V_{IHMIN} + 0.15)$
  - $T_F = 0.9 \text{ VDD}$  to  $(V_{ILMAX} - 0.15)$

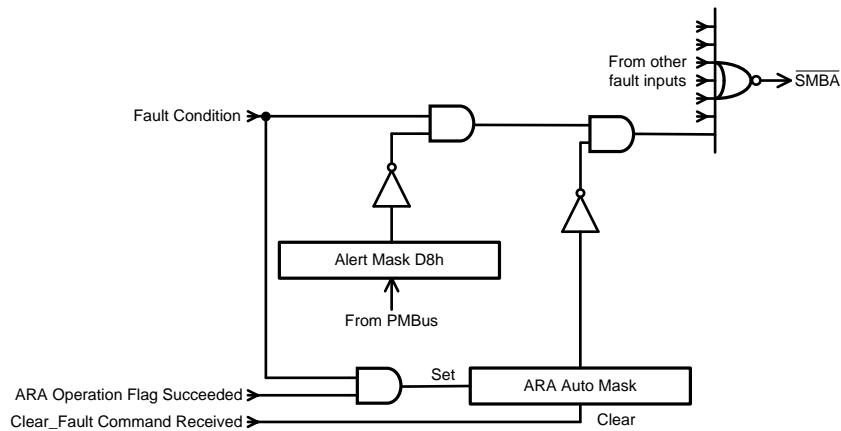
## SMBA RESPONSE

The SMBA effectively has two masks:

1. The Alert Mask Register at D8h, and
2. The ARA Automatic Mask.

The ARA Automatic Mask is a mask that is set in response to a successful ARA read. An ARA read operation returns the PMBus address of the lowest addressed part on the bus that has its SMBA asserted. A successful ARA read means that THIS part was the one that returned its address. When a part responds to the ARA read, it releases the SMBA signal. When the last part on the bus that has an SMBA set has successfully reported its address, the SMBA signal will de-assert.

The way that the LM5064 releases the SMBA signal is by setting the ARA Automatic mask bit for all fault conditions present at the time of the ARA read. All status registers will still show the fault condition, but it will not generate and SMBA on that fault again until the ARA Automatic mask is cleared by the host issuing a CLEAR\_FAULTS command to this part. This should be done as a routine part of servicing an SMBA condition on a part, even if the ARA read is not done. [Figure 21](#) depicts a schematic version of this flow.



**Figure 21. Typical Flow Schematic for SMBA Fault**

**REVISION HISTORY**

| <b>Changes from Revision D (February 2013) to Revision E</b> | <b>Page</b> |
|--|-------------|
| • Changed layout of National Data Sheet to TI format .....   | 54          |

**PACKAGING INFORMATION**

| Orderable part number | Status<br>(1) | Material type<br>(2) | Package   Pins    | Package qty   Carrier | RoHS<br>(3) | Lead finish/<br>Ball material<br>(4) | MSL rating/<br>Peak reflow<br>(5) | Op temp (°C) | Part marking<br>(6) |
|-----------------------|---------------|----------------------|-------------------|-----------------------|-------------|--------------------------------------|-----------------------------------|--------------|---------------------|
| LM5064PMH/NOPB        | Active        | Production           | HTSSOP (PWP)   28 | 48   TUBE             | Yes         | SN                                   | Level-3-260C-168 HR               | -40 to 125   | LM5064<br>PMH       |
| LM5064PMH/NOPB.A      | Active        | Production           | HTSSOP (PWP)   28 | 48   TUBE             | Yes         | SN                                   | Level-3-260C-168 HR               | -40 to 125   | LM5064<br>PMH       |
| LM5064PMHE/NOPB       | Active        | Production           | HTSSOP (PWP)   28 | 250   SMALL T&R       | Yes         | SN                                   | Level-3-260C-168 HR               | -40 to 125   | LM5064<br>PMH       |
| LM5064PMHE/NOPB.A     | Active        | Production           | HTSSOP (PWP)   28 | 250   SMALL T&R       | Yes         | SN                                   | Level-3-260C-168 HR               | -40 to 125   | LM5064<br>PMH       |
| LM5064PMHX/NOPB       | Active        | Production           | HTSSOP (PWP)   28 | 2500   LARGE T&R      | Yes         | SN                                   | Level-3-260C-168 HR               | -40 to 125   | LM5064<br>PMH       |
| LM5064PMHX/NOPB.A     | Active        | Production           | HTSSOP (PWP)   28 | 2500   LARGE T&R      | Yes         | SN                                   | Level-3-260C-168 HR               | -40 to 125   | LM5064<br>PMH       |

<sup>(1)</sup> **Status:** For more details on status, see our [product life cycle](#).

<sup>(2)</sup> **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

<sup>(4)</sup> **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

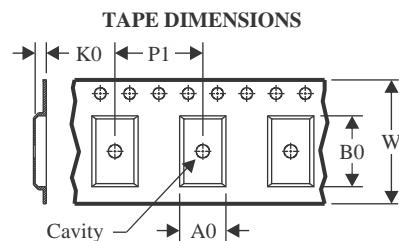
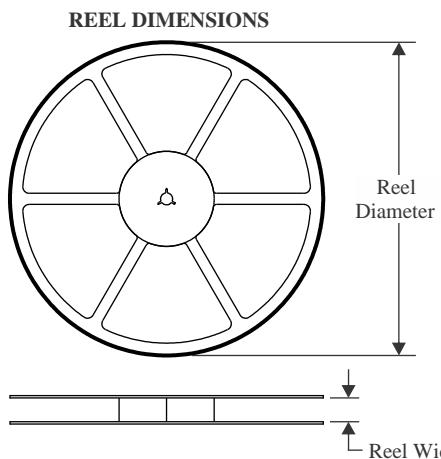
<sup>(6)</sup> **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

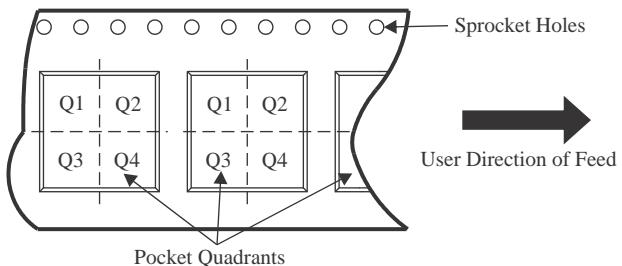
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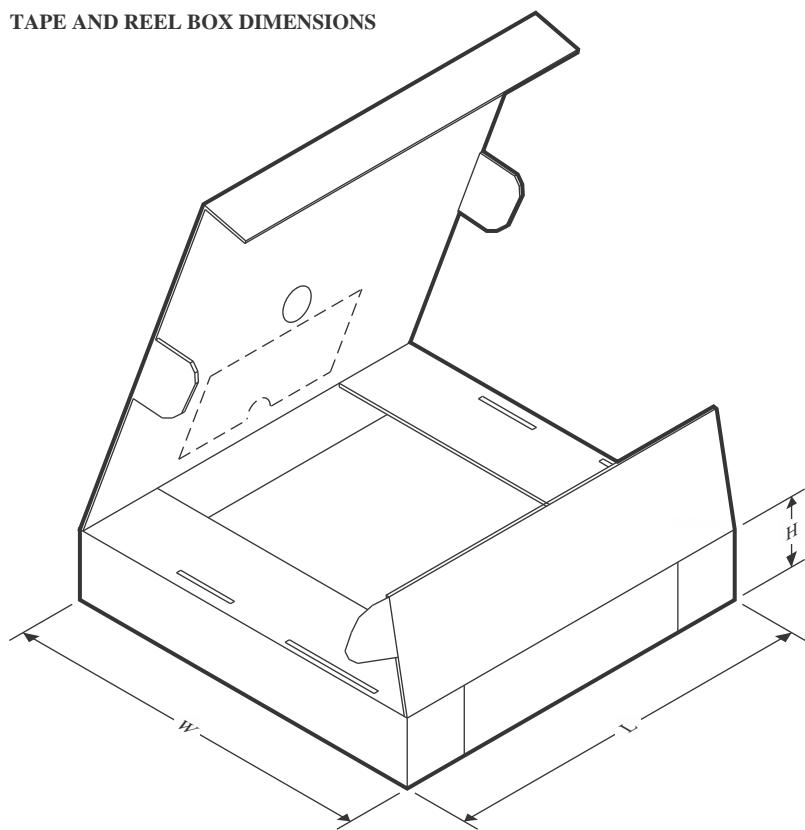
**TAPE AND REEL INFORMATION**


|    |   |
|----|---|
| A0 | Dimension designed to accommodate the component width     |
| B0 | Dimension designed to accommodate the component length    |
| K0 | Dimension designed to accommodate the component thickness |
| W  | Overall width of the carrier tape                         |
| P1 | Pitch between successive cavity centers                   |

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


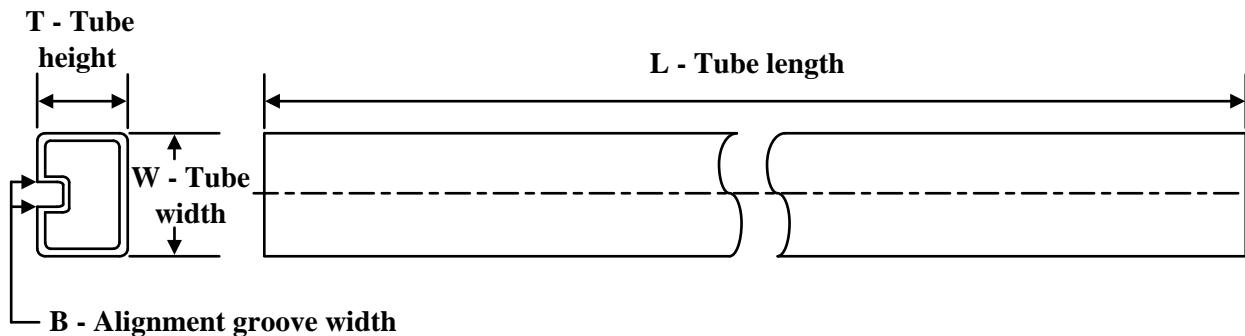
\*All dimensions are nominal

| Device          | Package Type | Package Drawing | Pins | SPQ  | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|-----------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| LM5064PMHE/NOPB | HTSSOP       | PWP             | 28   | 250  | 178.0              | 16.4               | 6.95    | 10.0    | 1.7     | 8.0     | 16.0   | Q1            |
| LM5064PMHX/NOPB | HTSSOP       | PWP             | 28   | 2500 | 330.0              | 16.4               | 6.95    | 10.0    | 1.7     | 8.0     | 16.0   | Q1            |

**TAPE AND REEL BOX DIMENSIONS**


\*All dimensions are nominal

| Device          | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|-----------------|--------------|-----------------|------|------|-------------|------------|-------------|
| LM5064PMHE/NOPB | HTSSOP       | PWP             | 28   | 250  | 208.0       | 191.0      | 35.0        |
| LM5064PMHX/NOPB | HTSSOP       | PWP             | 28   | 2500 | 356.0       | 356.0      | 36.0        |

**TUBE**


\*All dimensions are nominal

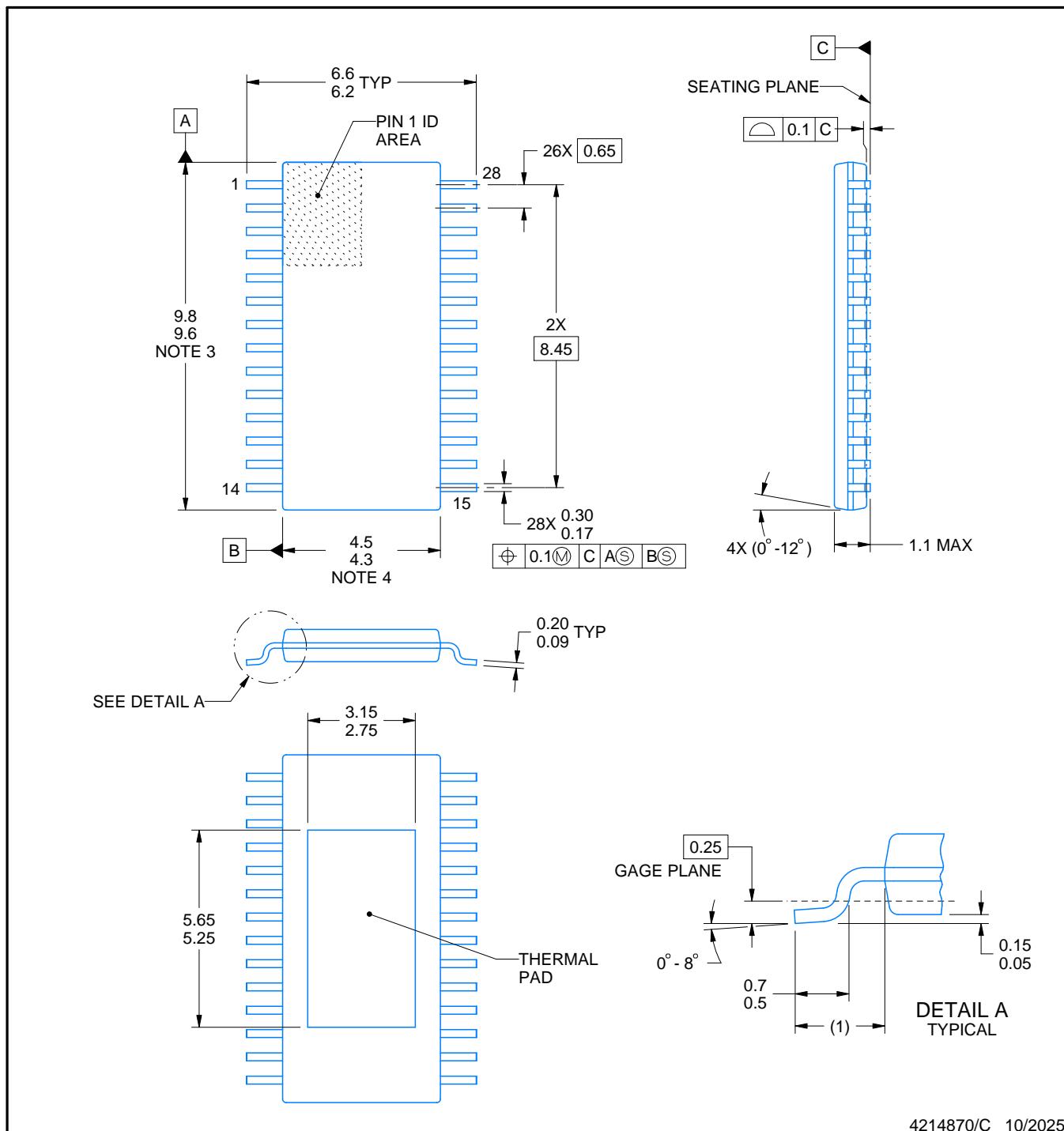
| Device           | Package Name | Package Type | Pins | SPQ | L (mm) | W (mm) | T (μm) | B (mm) |
|------------------|--------------|--------------|------|-----|--------|--------|--------|--------|
| LM5064PMH/NOPB   | PWP          | HTSSOP       | 28   | 48  | 495    | 8      | 2514.6 | 4.06   |
| LM5064PMH/NOPB.A | PWP          | HTSSOP       | 28   | 48  | 495    | 8      | 2514.6 | 4.06   |

## PACKAGE OUTLINE

PWP0028A

**PowerPAD™ - 1.1 mm max height**

## PLASTIC SMALL OUTLINE



4214870/C 10/2025

## NOTES:

PowerPAD is a trademark of Texas Instruments.

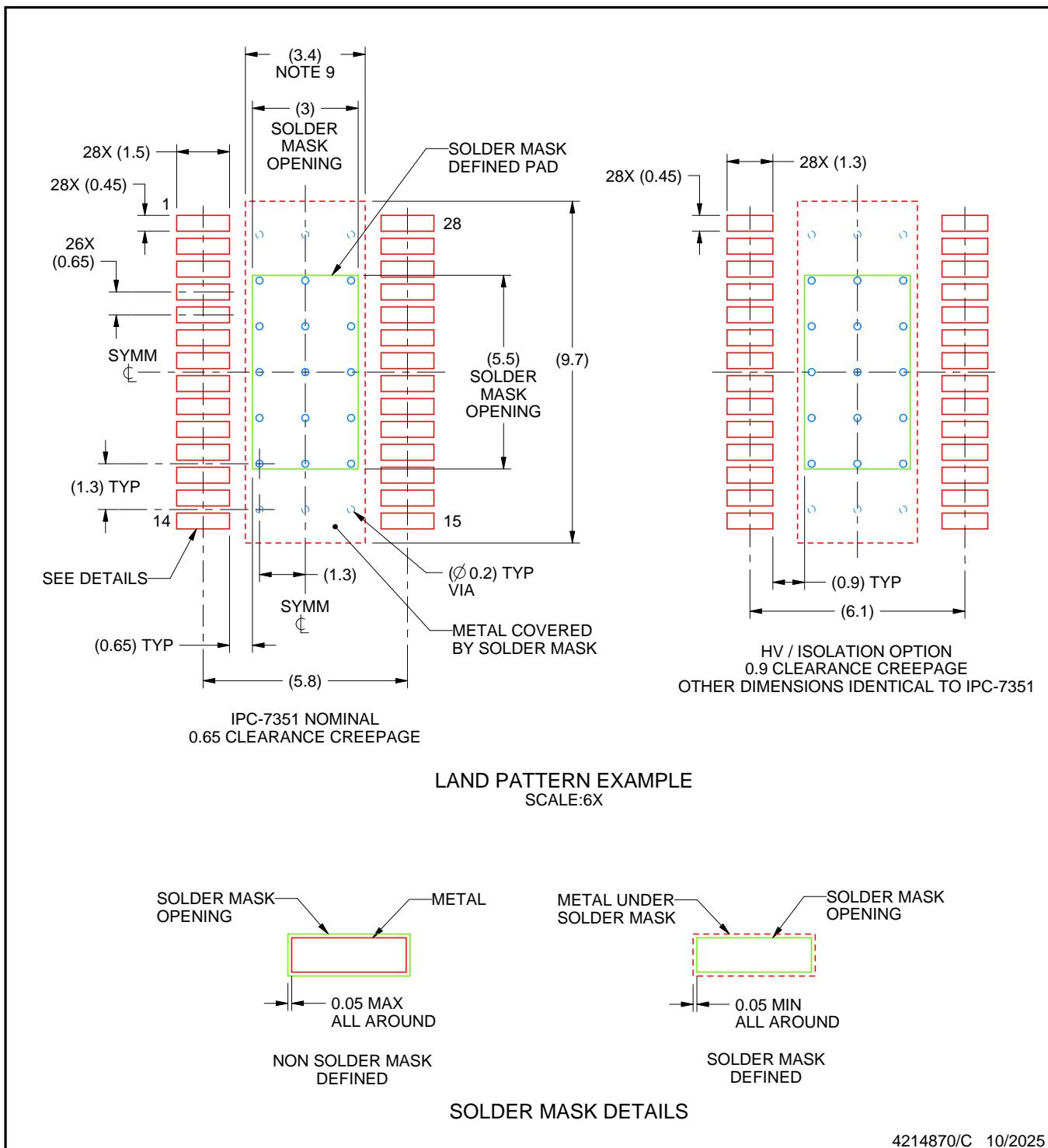
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.
5. Reference JEDEC registration MO-153, variation AET.

# EXAMPLE BOARD LAYOUT

PWP0028A

PowerPAD™ - 1.1 mm max height

PLASTIC SMALL OUTLINE



NOTES: (continued)

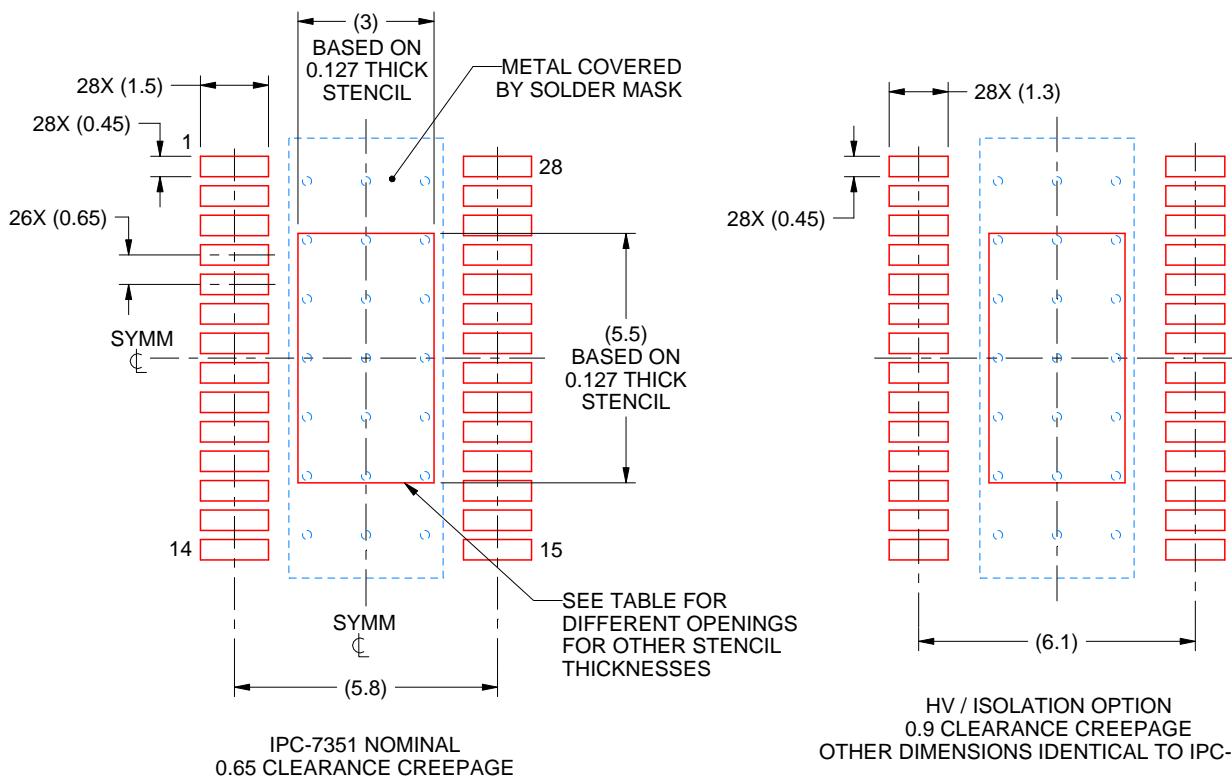
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature numbers SLMA002 ([www.ti.com/lit/slma002](http://www.ti.com/lit/slma002)) and SLMA004 ([www.ti.com/lit/slma004](http://www.ti.com/lit/slma004)).
9. Size of metal pad may vary due to creepage requirement.

# EXAMPLE STENCIL DESIGN

PWP0028A

PowerPAD™ - 1.1 mm max height

PLASTIC SMALL OUTLINE



SOLDER PASTE EXAMPLE  
EXPOSED PAD  
100% PRINTED SOLDER COVERAGE AREA  
SCALE:6X

| STENCIL THICKNESS | SOLDER STENCIL OPENING |
|-------------------|------------------------|
| 0.1               | 3.55 X 6.37            |
| 0.127             | 3.0 X 5.5 (SHOWN)      |
| 0.152             | 2.88 X 5.16            |
| 0.178             | 2.66 X 4.77            |

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NOTES: (continued)

10. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
11. Board assembly site may have different recommendations for stencil design.

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